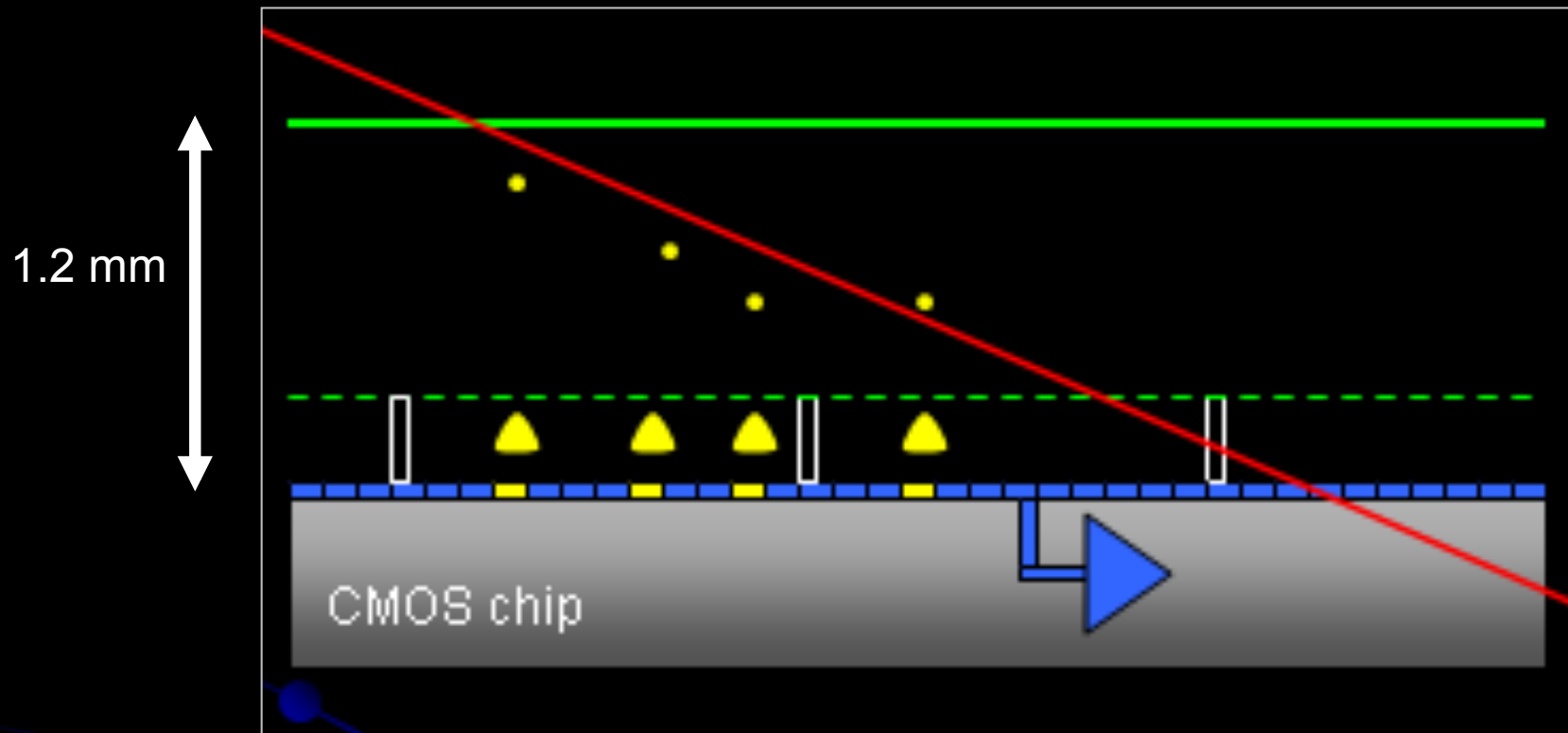


# gasless gaseous detectors

Harry van der Graaf  
Nikhef, Amsterdam

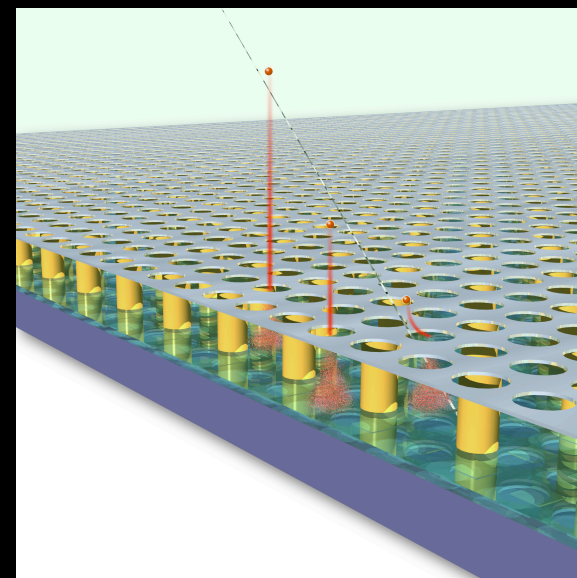
Instrumentation Seminar  
DESY, Aug 13, 2010

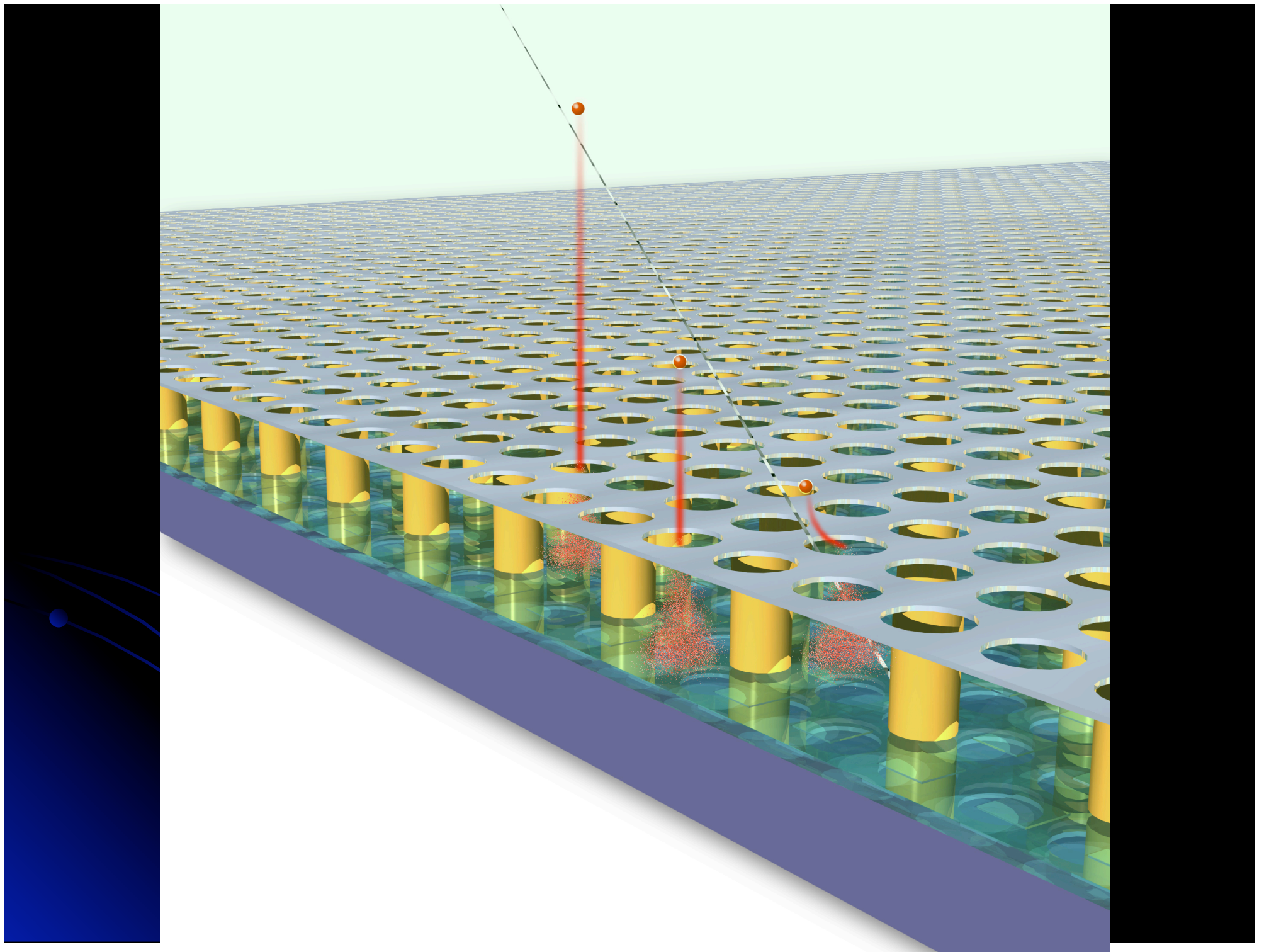


GridPix and  
Gas On Slimmed Silicon Pixels

Gossip: replacement of Si tracker

Essential: thin gas layer (1.2 mm)





## The MediPix2 pixel CMOS chip

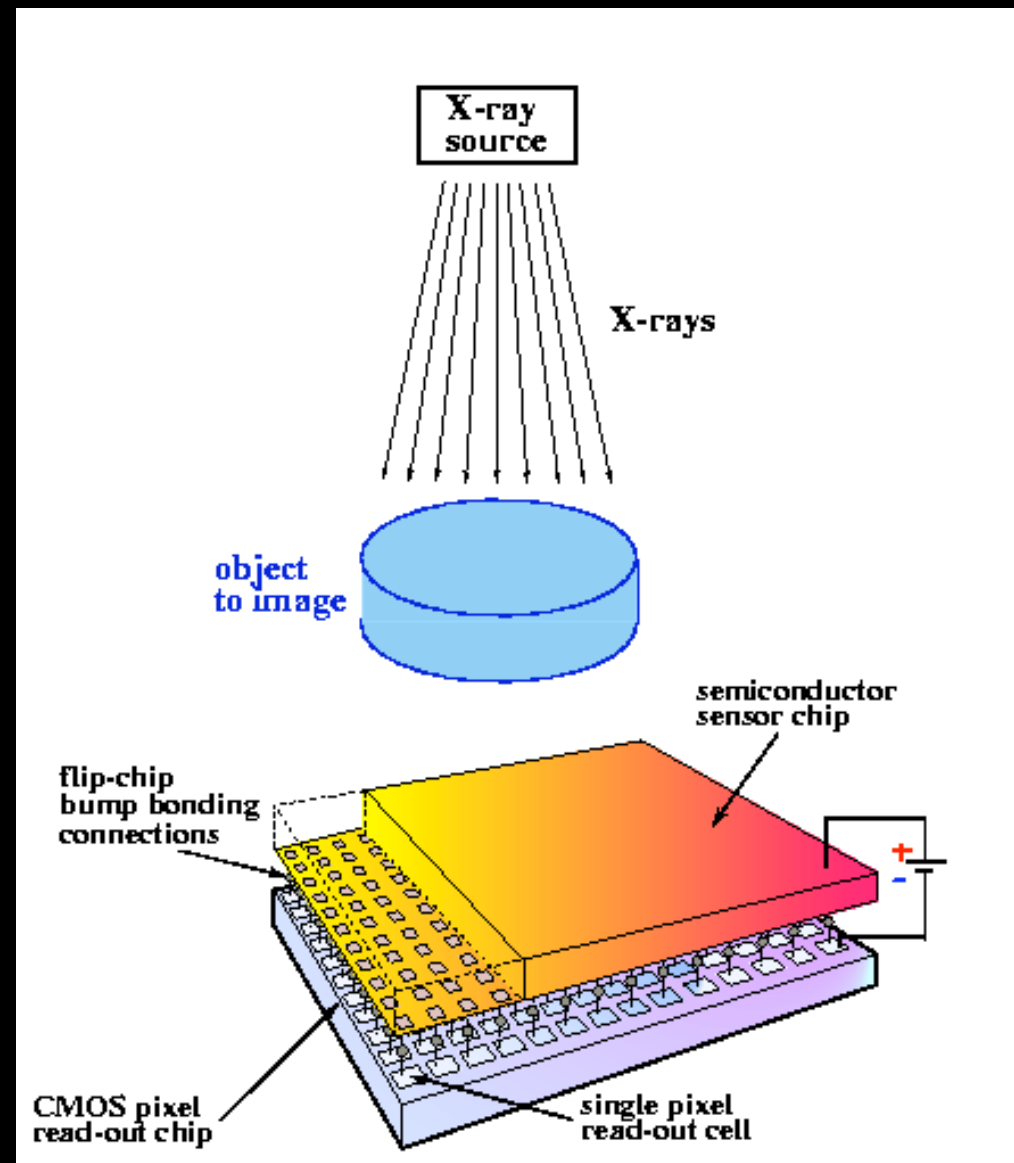
256 x 256 pixels

pixel:  $55 \times 55 \mu\text{m}^2$

per pixel:

- preamp
- shaper
- 2 discr.
- Thresh. DAQ
- 14 bit counter

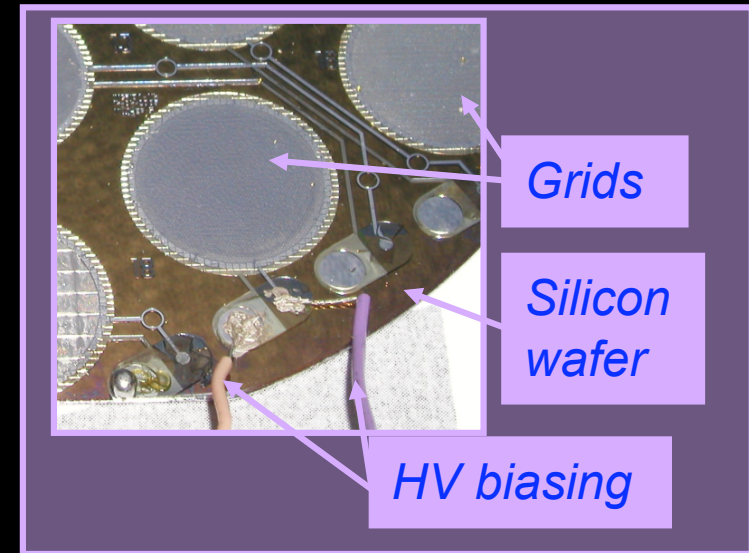
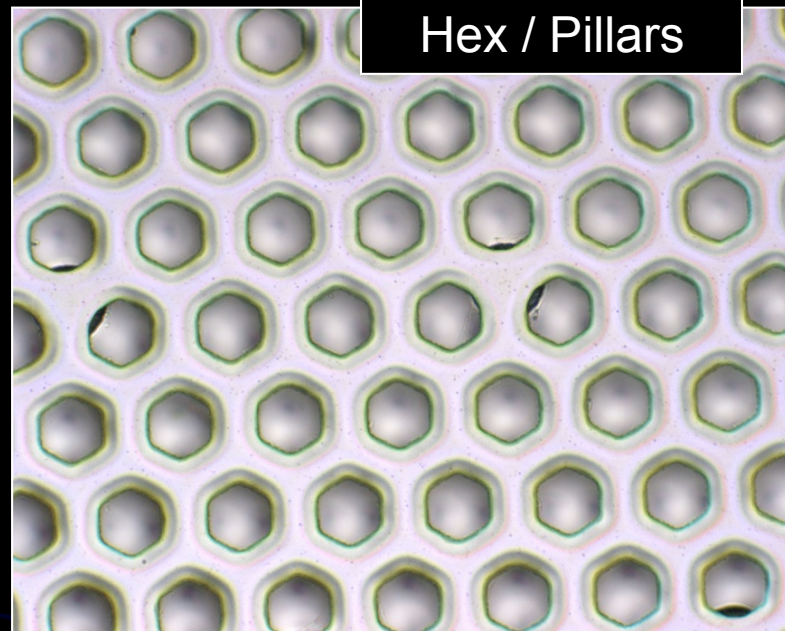
- enable counting
- stop counting
- readout image frame
- reset



We apply the 'naked' MediPix2 chip  
without X-ray convertor!



# Wafer post-processing: InGrid

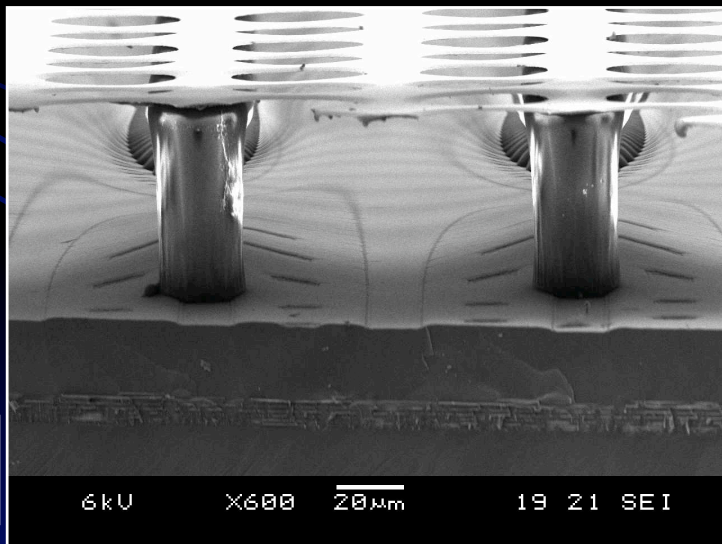
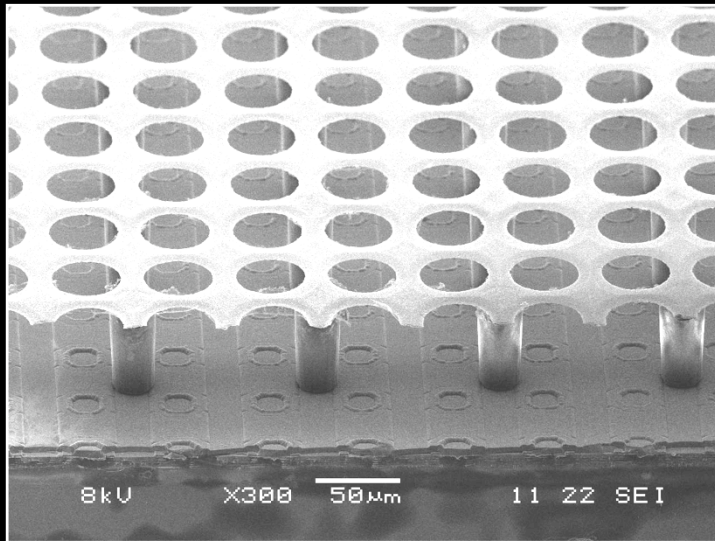


InGrid: an Integrated Grid on Si (wafers or chips)

- perfect alignment of grid holes and pixel pads
- small pillars Ø, hidden pillars, full pixel area coverage
- Sub-micron precision: homogeneity
- Monolithic readout device: integrated electron amplifier

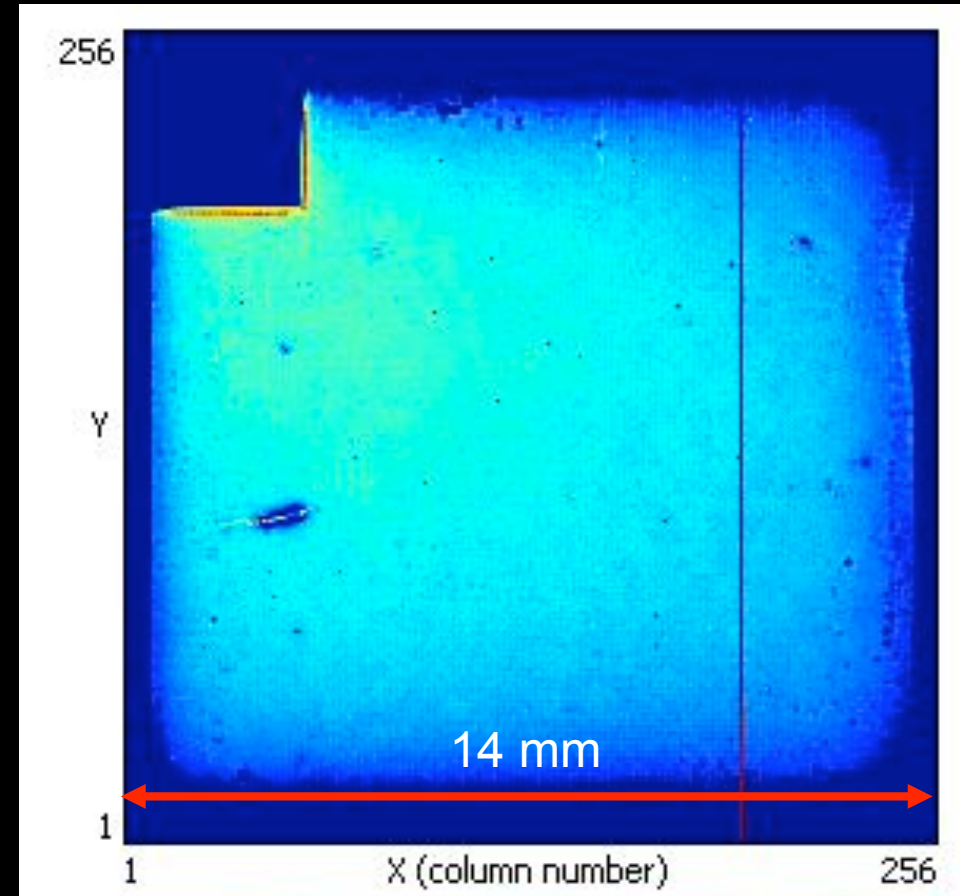
# Full post-processing of a TimePix

- Timepix chip + SiProt + Ingrid:



MESA+

IMT  
Neuchatel



“Uniform”

Charge mode

# Gas instead of Si

## Pro:

- no radiation damage in sensor: gas is exchanged
- modest pixel (analog) input circuitry: low power, little space
- no bias current: simple input circuit
- low detector material budget: 0.06 % radiation length/layer  
typical: Si foil. New mechanical concepts
- low power dissipation : little FE power ( $2 \mu\text{W}/\text{pixel}$ ); no bias dissipation
- operates at room temperature (but other temperatures are OK)
- less sensitive for neutron and X-ray background
- 3D track info *per layer* if drift time is measured
- gas is cheap (and *very* cheap wrt. Si sensors!), and light

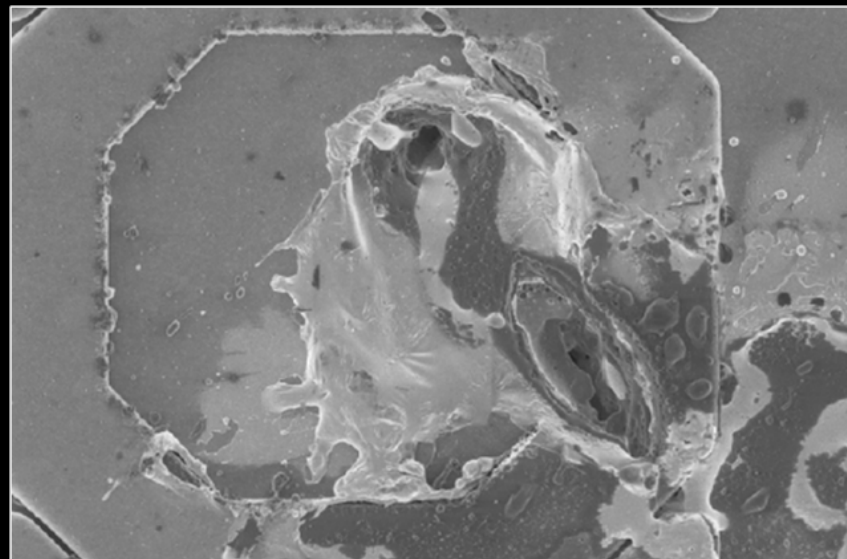
## Con:

- Gaseous chamber: discharges (sparks): destroy CMOS chip
- gas-filled proportional chamber: 'chamber ageing'
- limit in spatial resolution due to low primary gas-particle interaction statistics
- Needs gas flow
- Parallax error: 1 ns drift time measurement may be required
- diffusion of (drifting) electrons in gas limit spatial resolution



# But, are these good enough?

2006-2007 dead chips everywhere  
2007-2008 spark protection and  
Ingrid  
2008-2009 characterizing  
performance of GridPix



Cathode  
- Drift volume ( $\sim 0.1$ -few kV/cm)  
Grid  
- Gain region ( $\sim 50$ -150 kV/cm)  
Pixel readout chip



## Now with $\text{Si}_3\text{N}_4$ : lower dielectric constant

InGrid



amorphous Si ( $\epsilon_r = 11$ )

SiNitrade ( $\epsilon_r = 5$ )

7  $\mu\text{m}$  SiNitrade:  
Factor  $\sim 2$  more charge on input pad  
for normal (proportional) signals



# ... discharges are observed !

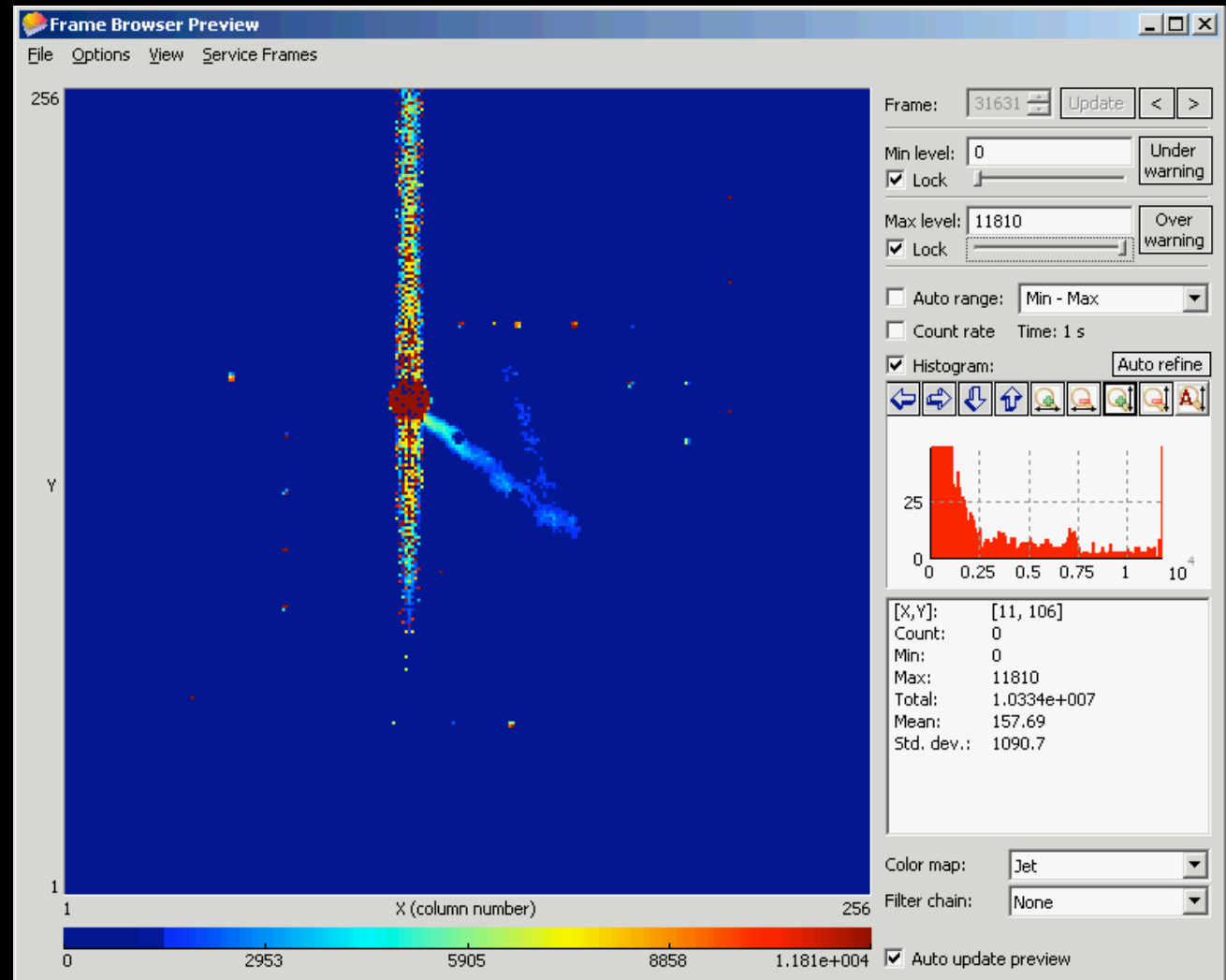
For the 1<sup>st</sup> time: image of discharges are being recorded

Round-shaped pattern of some 100 overflow pixels

Perturbations in the concerned column pixels

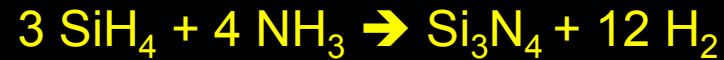
- Threshold
- Power

Chip keeps working

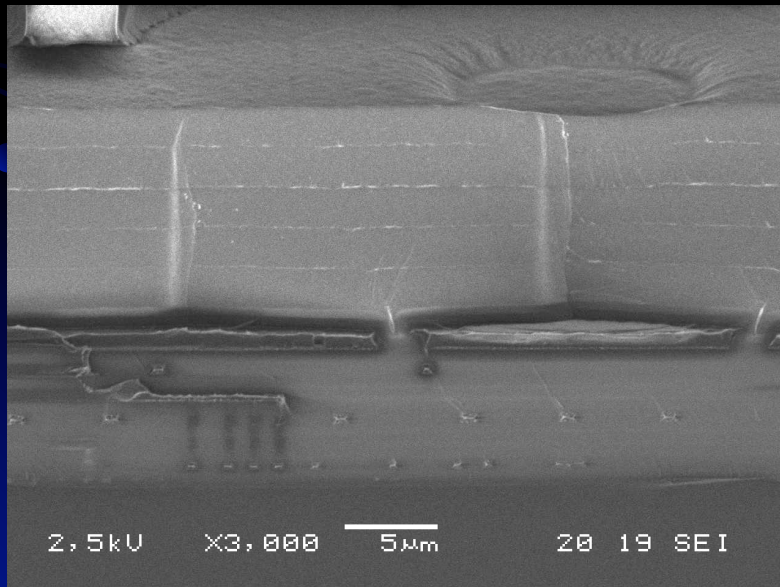


Protection layer of amorphous silicon: 2007

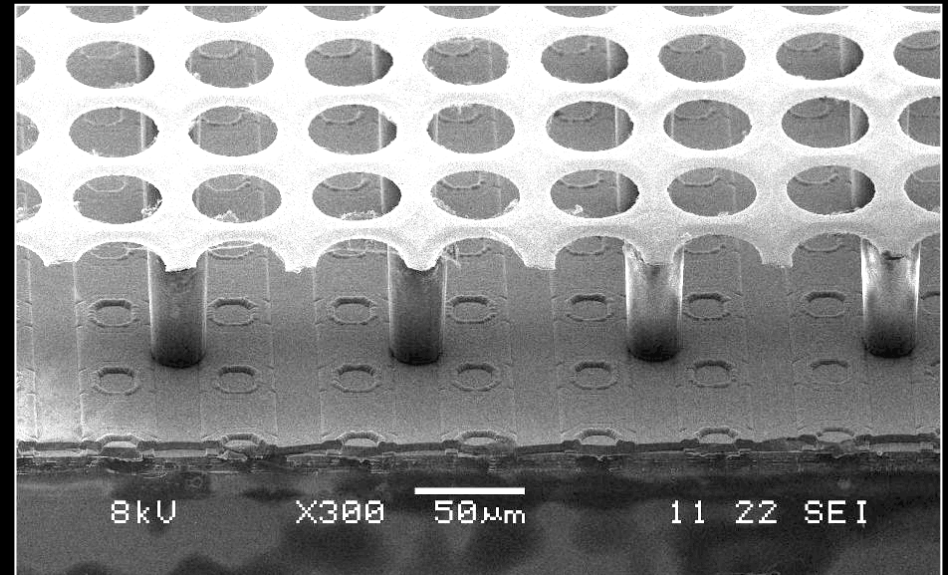
July 2008: protection layer made of  $\text{Si}_3\text{N}_4$  (Silicon Nitride), only 7  $\mu\text{m}$  thick



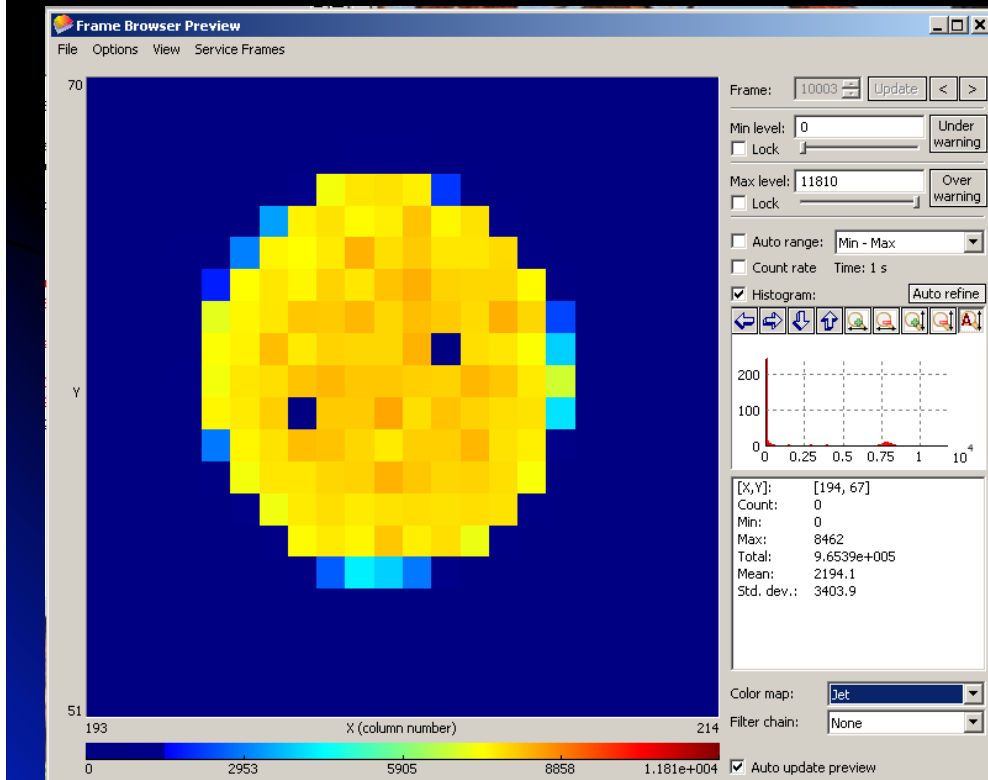
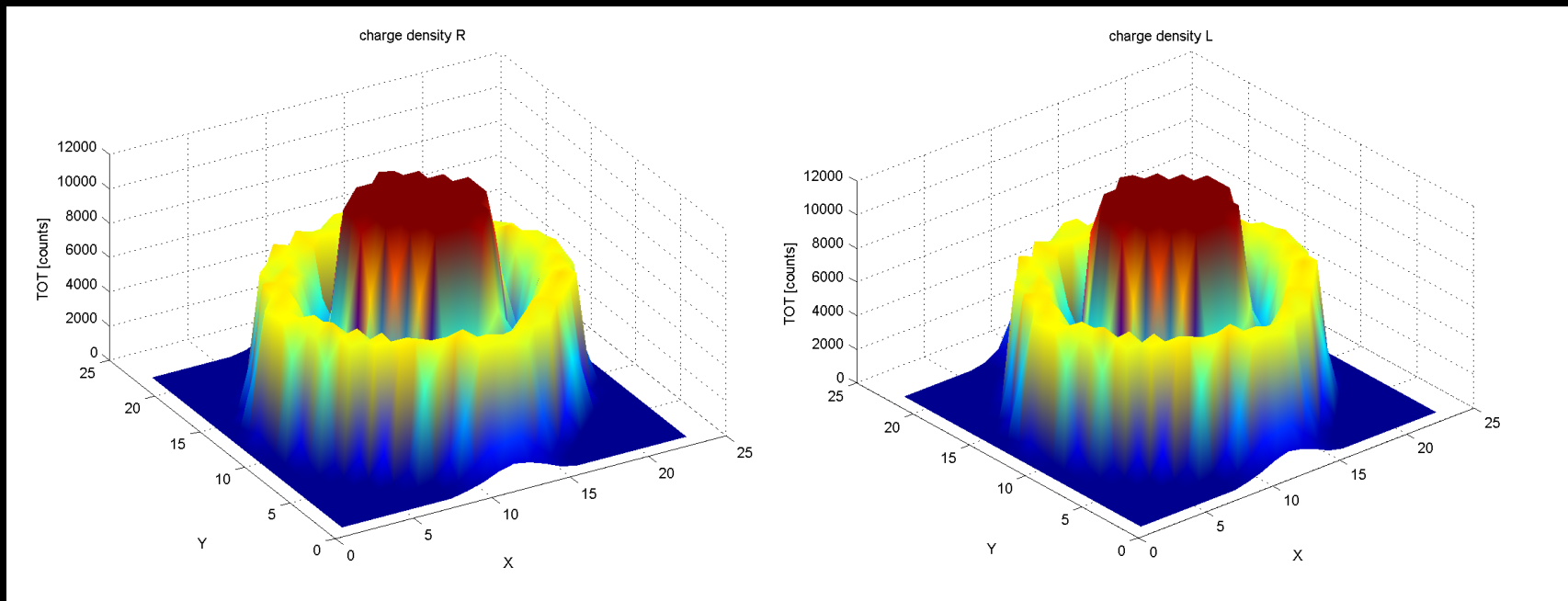
- Silicon Nitride is often applied as passivation layer: top finish of chips.
- With overdose of  $\text{SiH}_4$ : conductivity: high resistivity bulk material
- Favored material for bearings in turbo chargers, jet engines



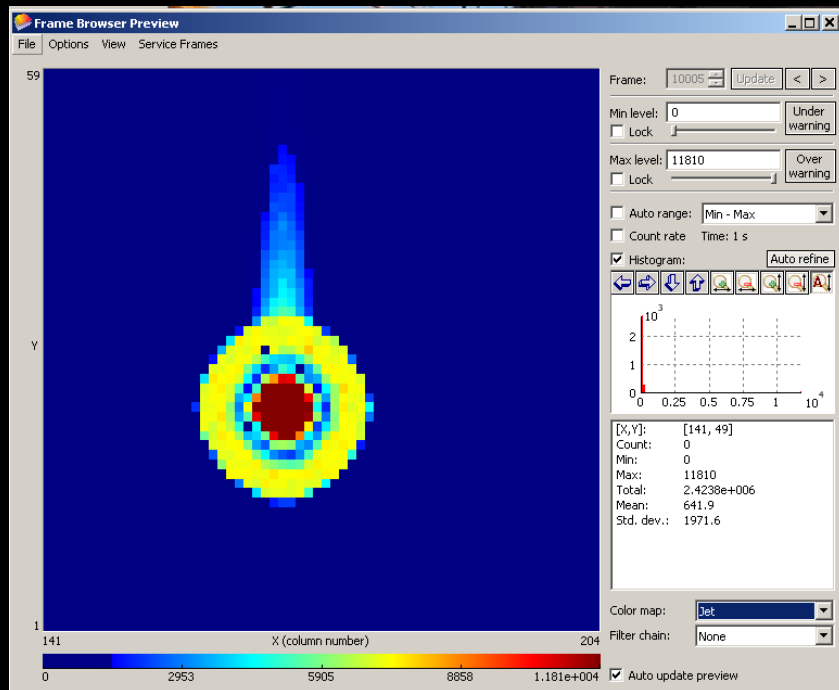
5 layers of  $\text{Si}_3\text{N}_4$



InGrid + a-Si:H



Discharge (protection) studies:  
Martin Fransen



Lorentz Force

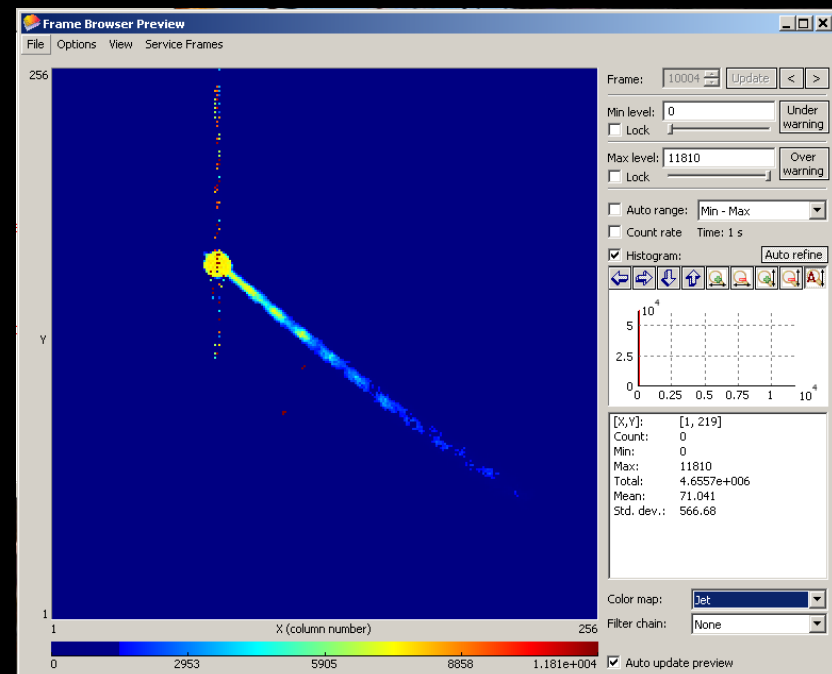
Skin Effect

$$F = E \cdot q$$

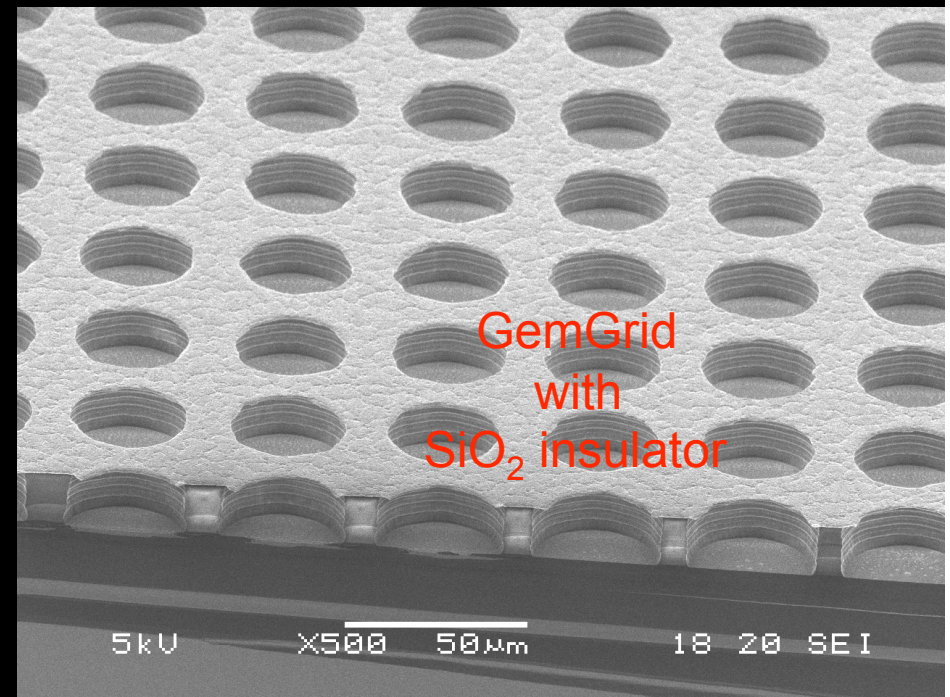
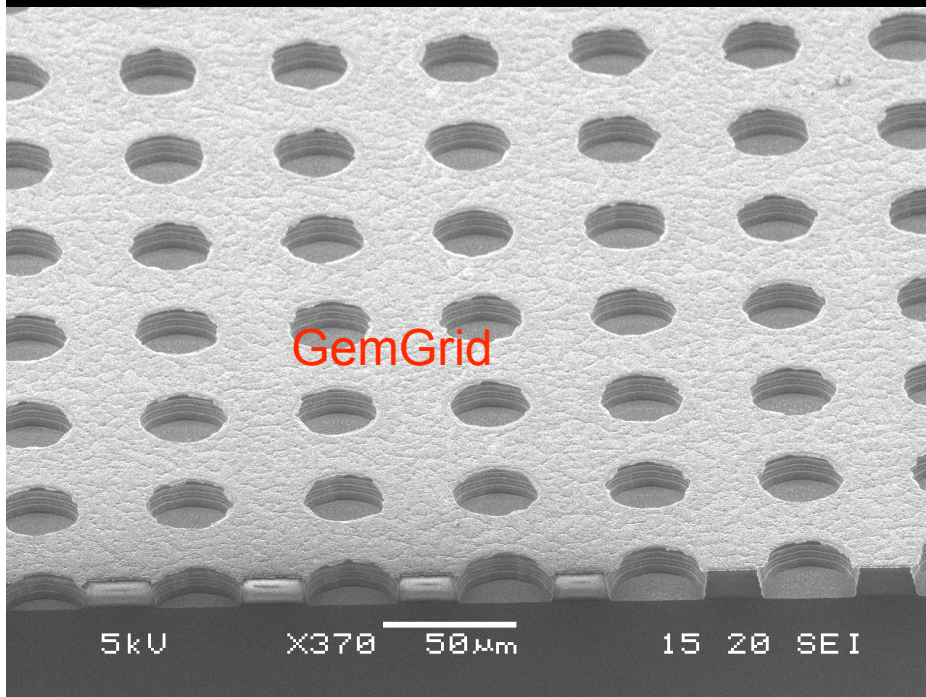
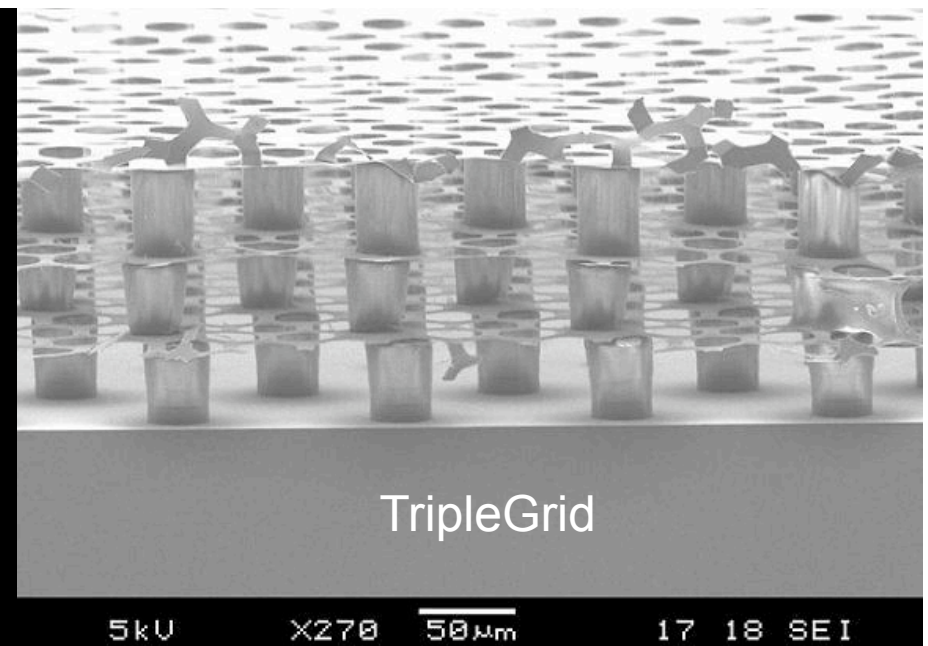
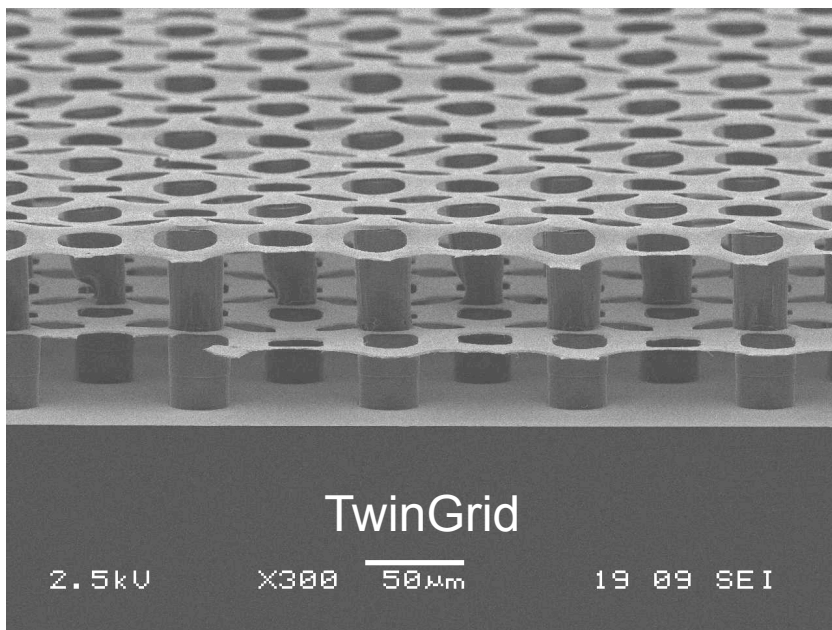
$$I = \sim 3A !$$



Improvement with Si Nitride



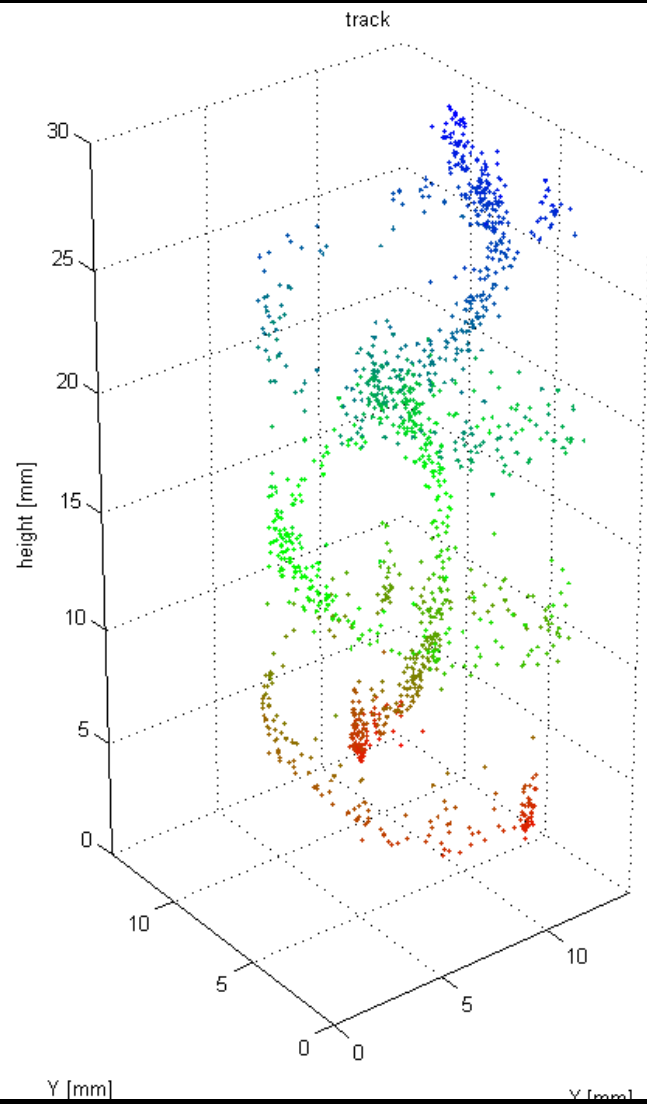






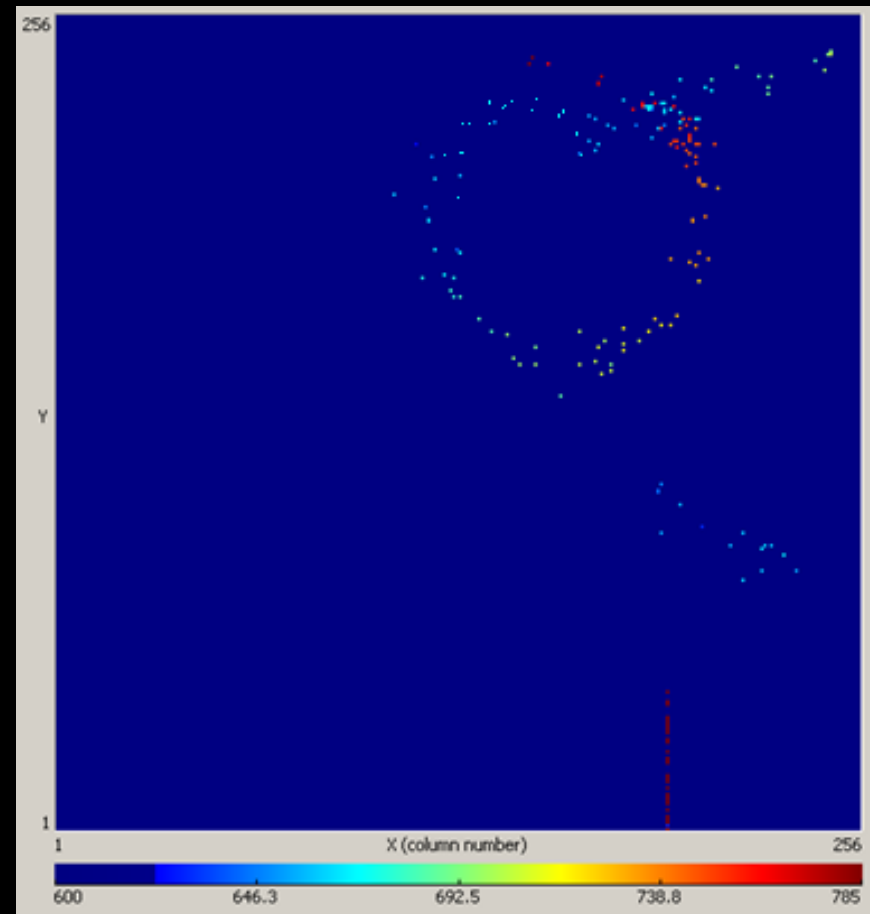
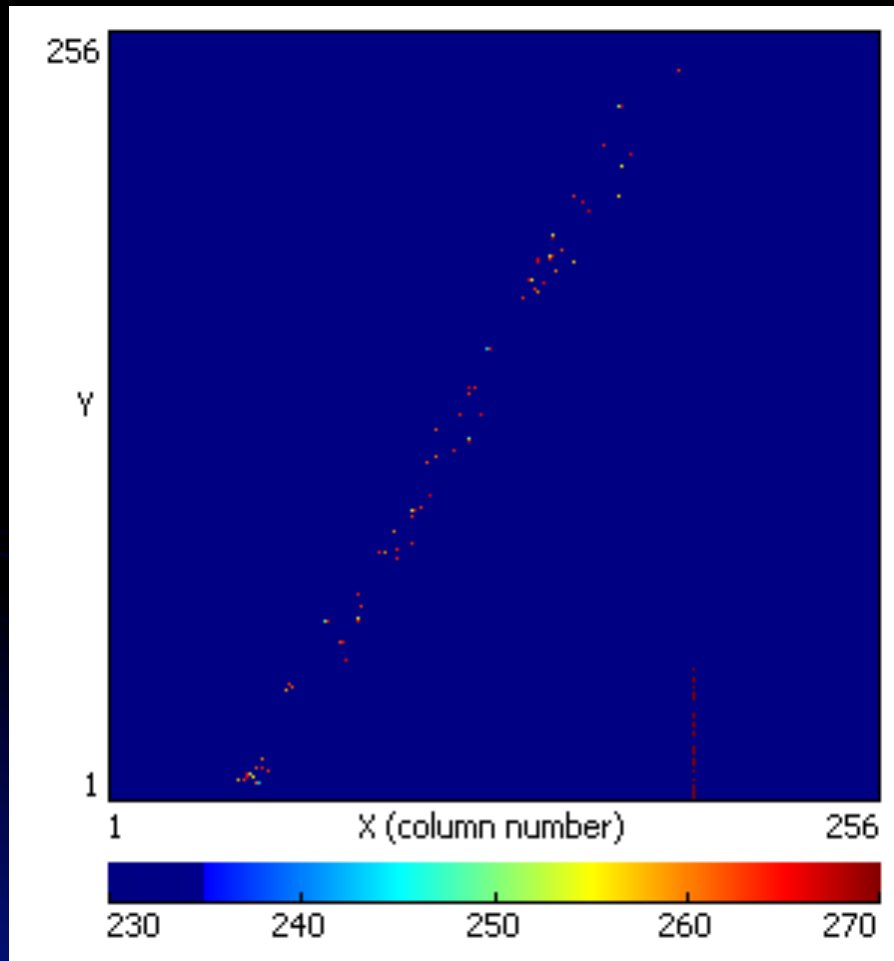
$^{90}\text{Sr}$   $\beta$  events

Gas: Ar/i-butane 80/20



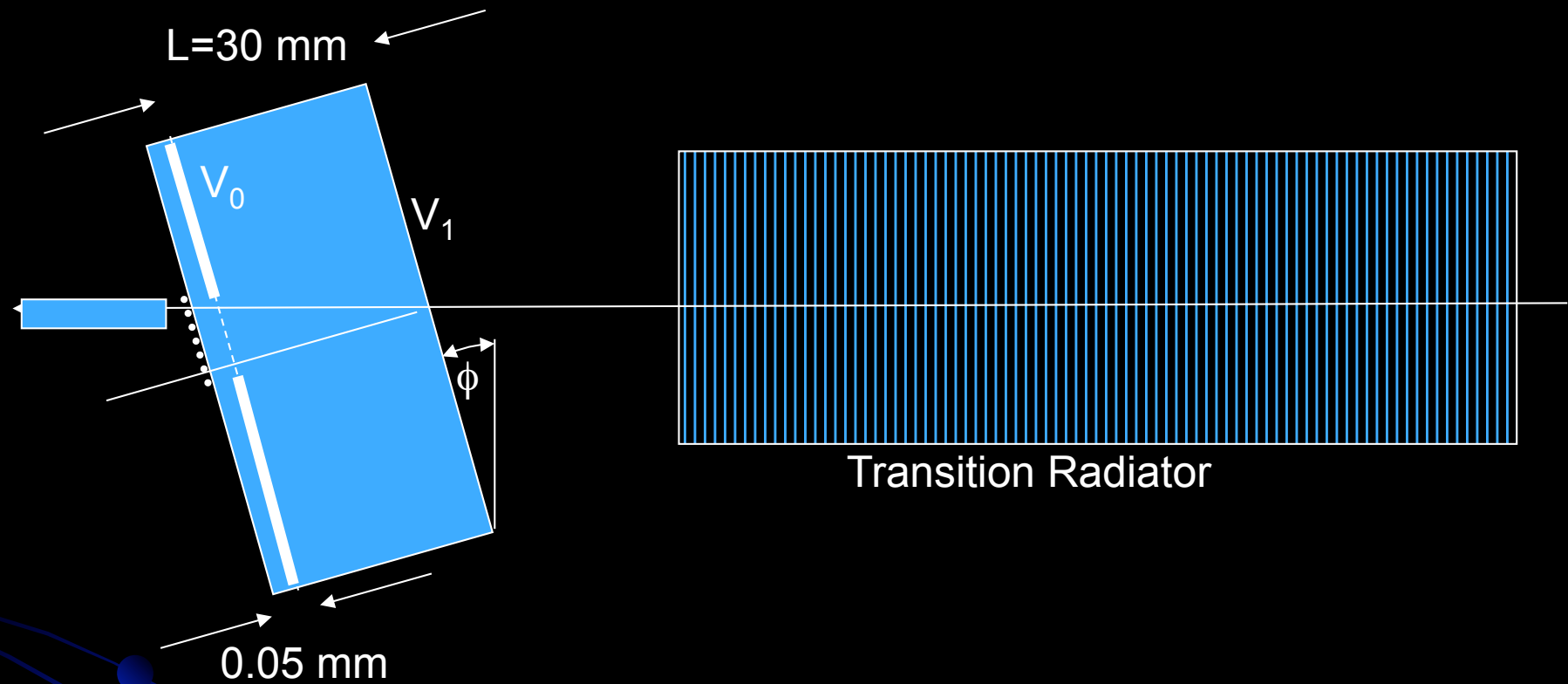
$B = 0.2 \text{ T}$

# Analysis of test beam data and cosmic muon data with GridPix



Colloquium Lucie de Nooij, Tuesday 13 January, 15h, H331

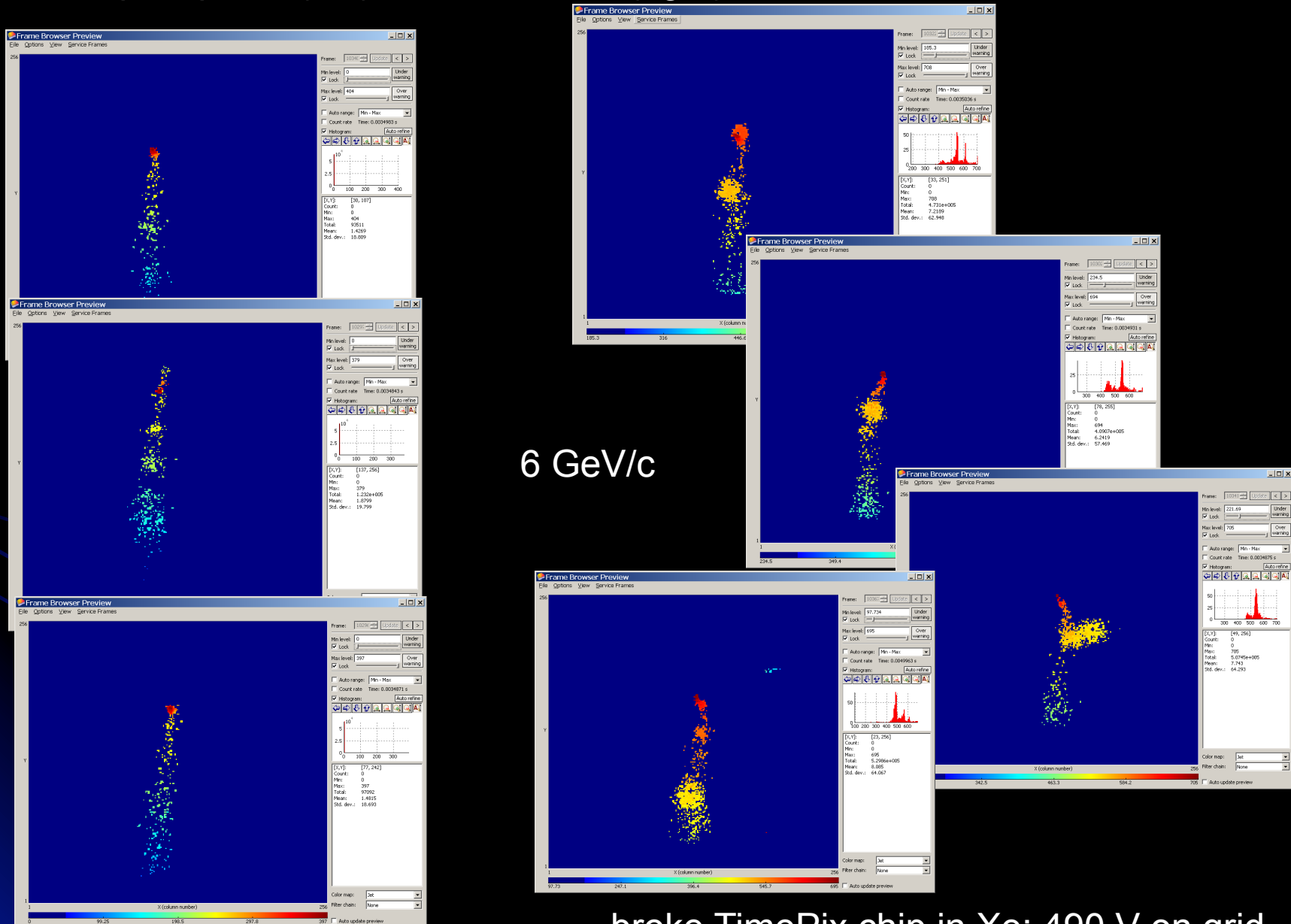
Testbeam April 2008  
PS/T9: electrons and pions, 1 – 15 GeV/c



! detection of Transition Radiation photons !

# Particle Identification

Samples pions (left) and electrons (right)



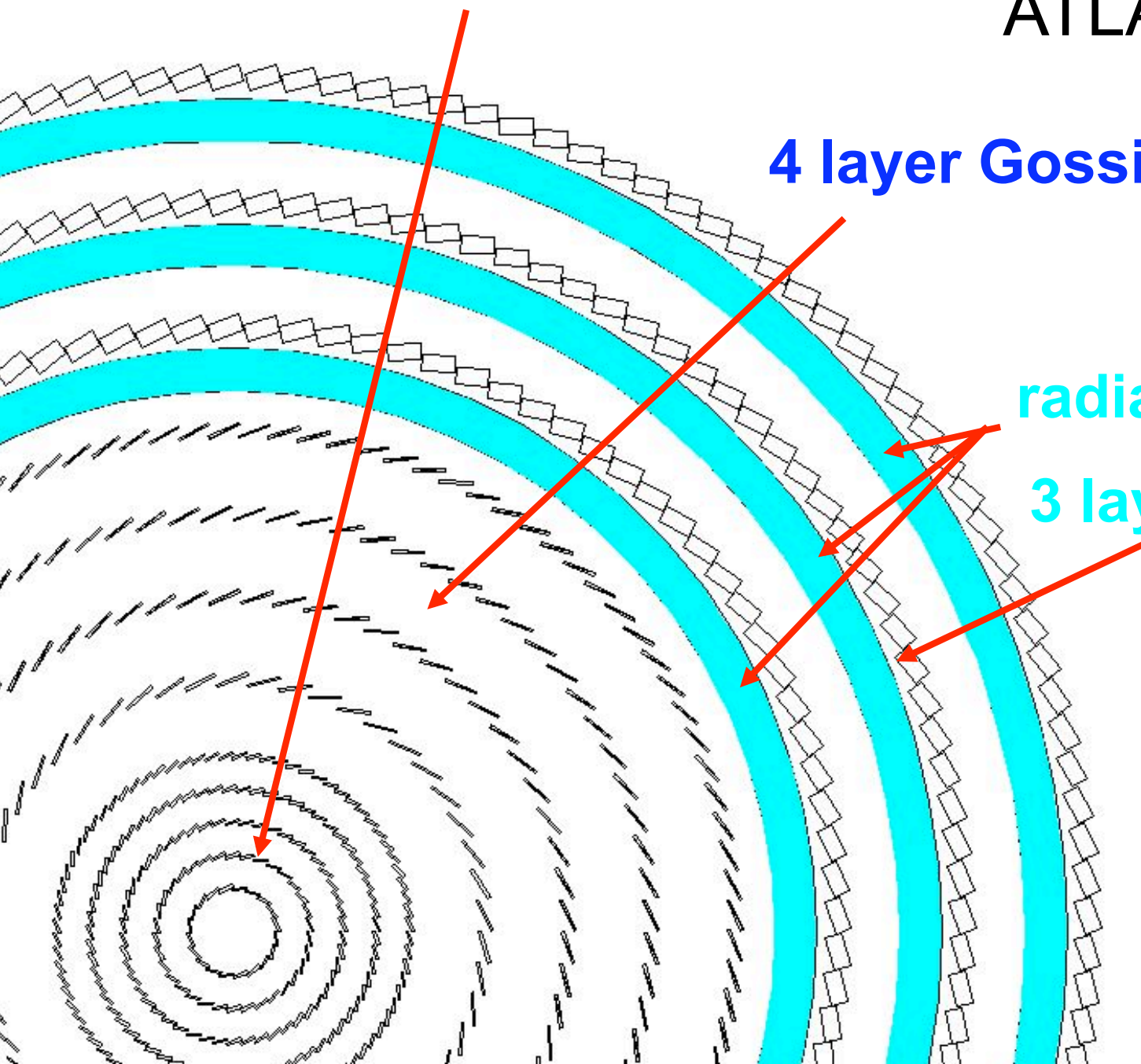
**5 (double) layer Gossip Pixel**

ATLAS Upgrade

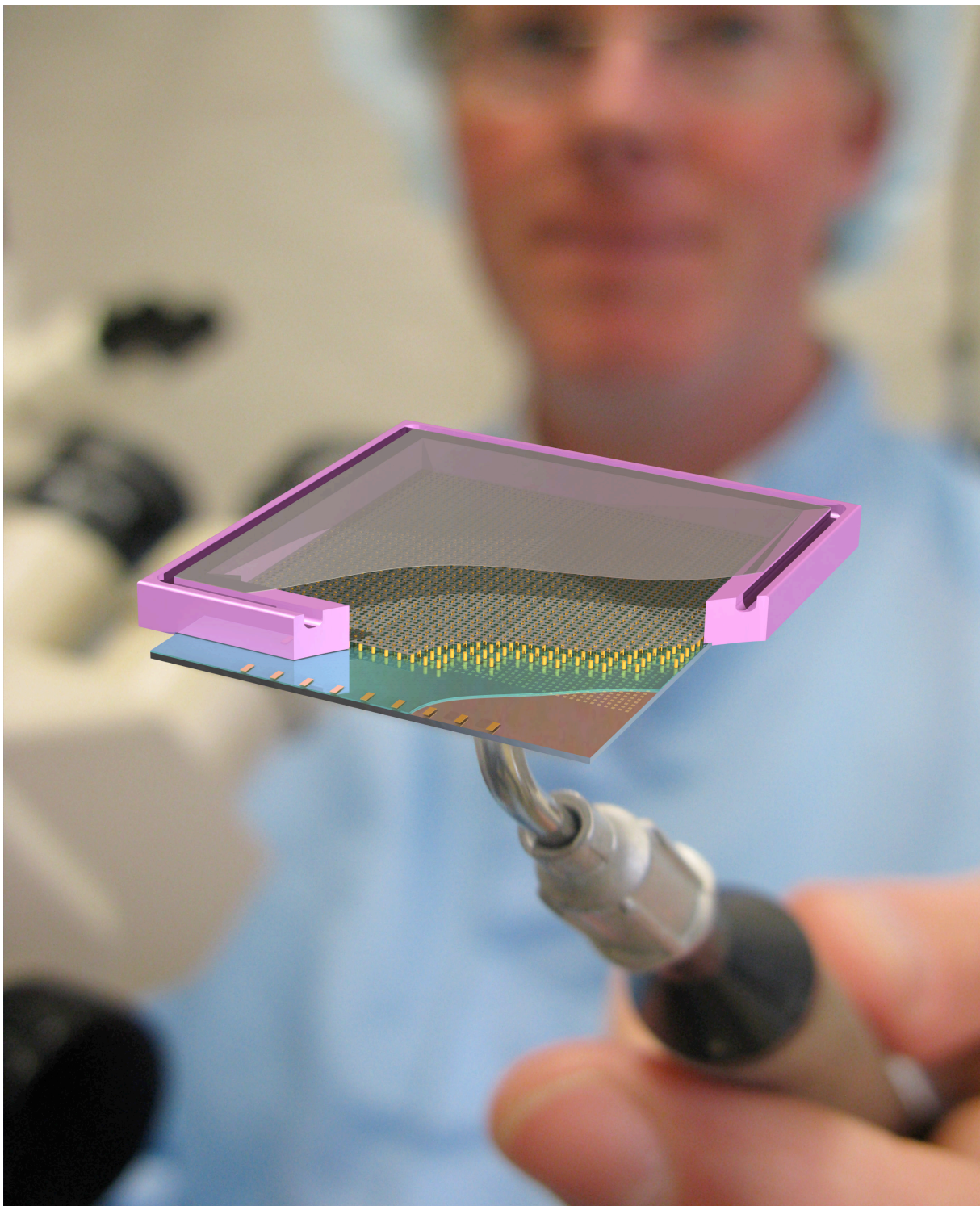
**4 layer Gossip Strixel**

**radiator**

**3 layers LVL1 (+ TRT)**





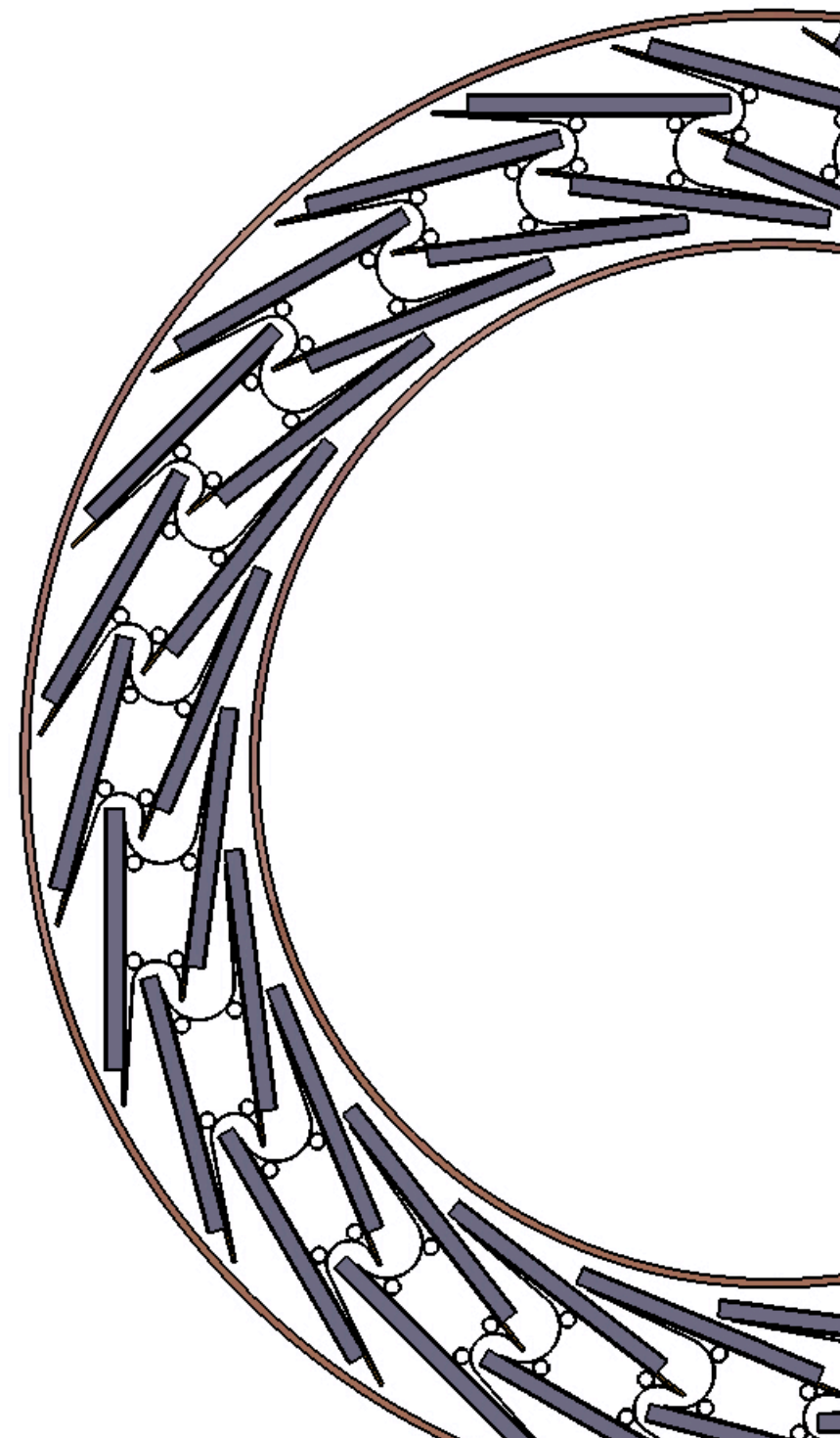
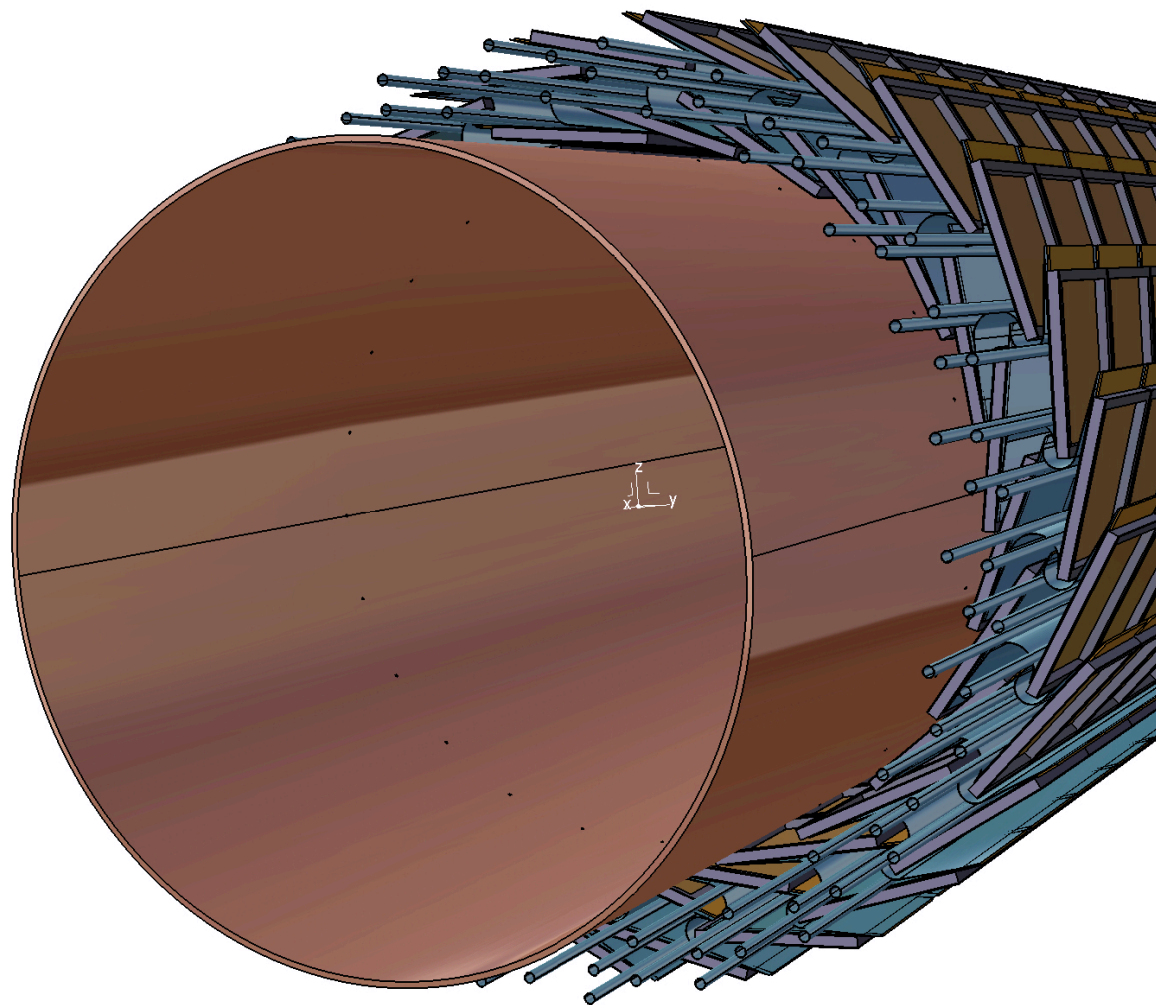


Vertex Pixel detector

Strixel detector

LVL1 trigger

TRT

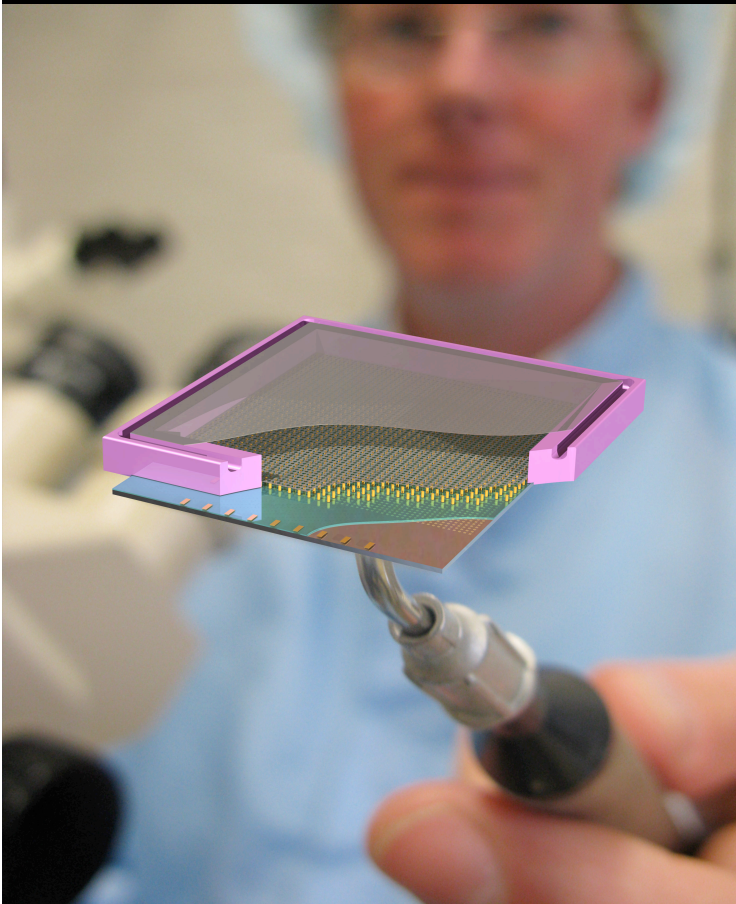


ATLAS:  
Gossip as vertex detector



## GridPix replacing the **Si Strip Tracker**:

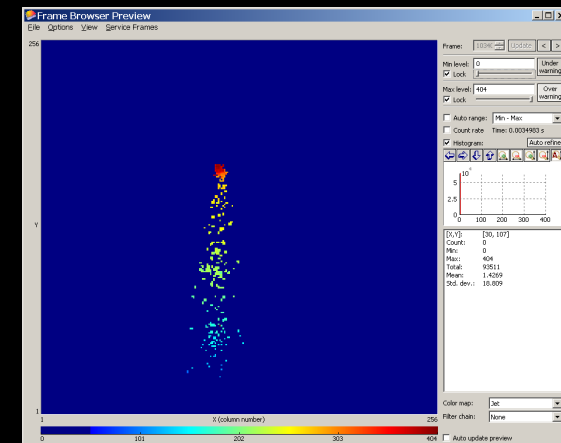
- huge surface: up to 200 m<sup>2</sup>
- replace strip sensor+ CMOS FE chips with strixel CMOS chips
- lower occupancy: thicker gas layer. more track info



- Cost: 10 + 10 \$ cm<sup>-1</sup> for Gossip
- ultralight: 0.2 % X<sub>0</sub>/layer
- Track segment info
- Many layers (> 10) feasible

projected track length  
is measure for momentum:

- directly available (LVL1)
- at no (extra) cost (mass, power)
- at larger R: gas drift gap  $\sim 20$  mm  
 $\sim 12$  BXs



LVL1 trigger from inner tracker

Requires fast on-board processing

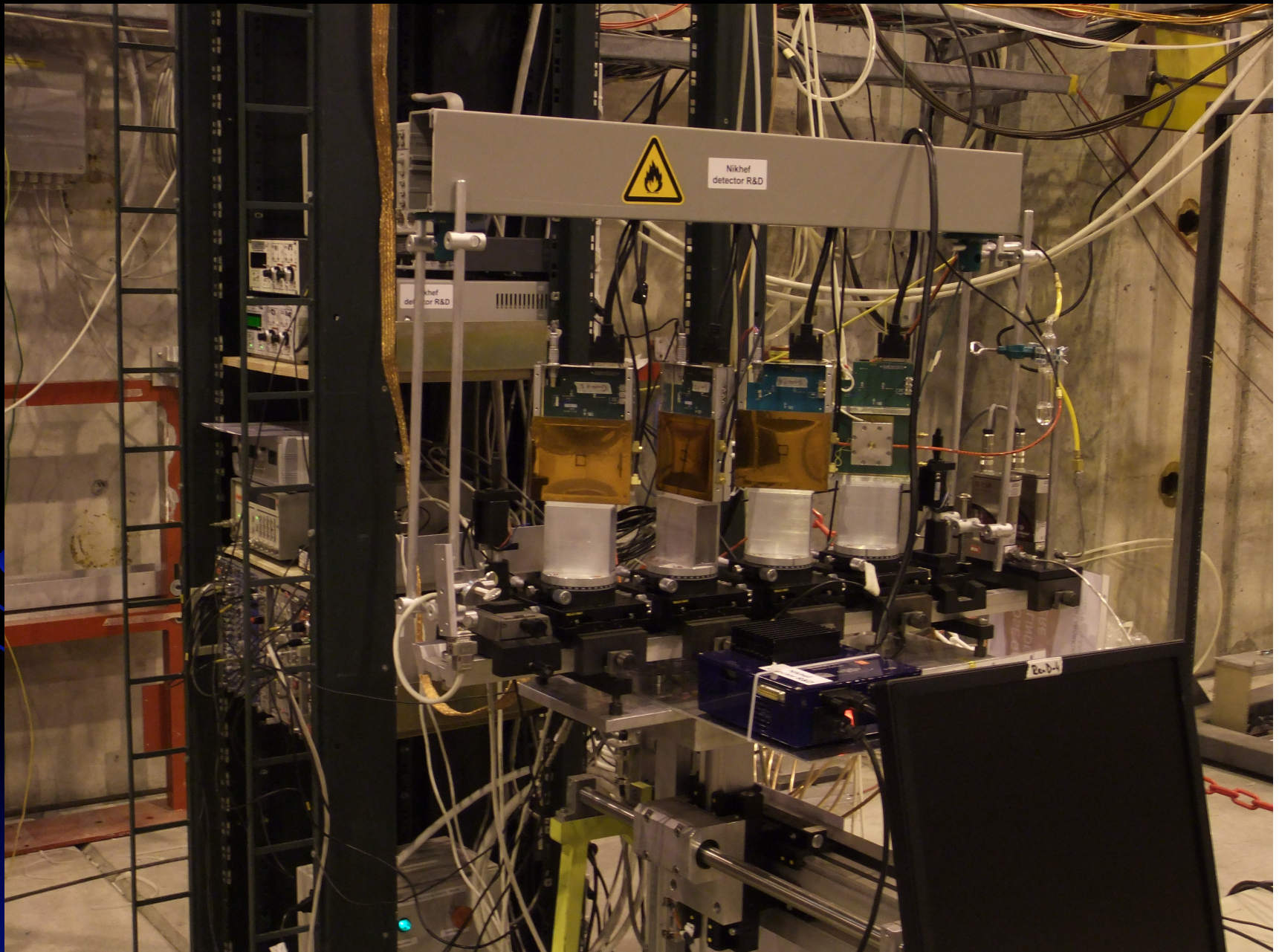
We are using 130 nm tech.

What about 45 nm tech?



# Test Beam (H4 at SPS, CERN) Aug 12, 2010

Martin, Victor, Fred, Harry  
Wilco, Sjoerd





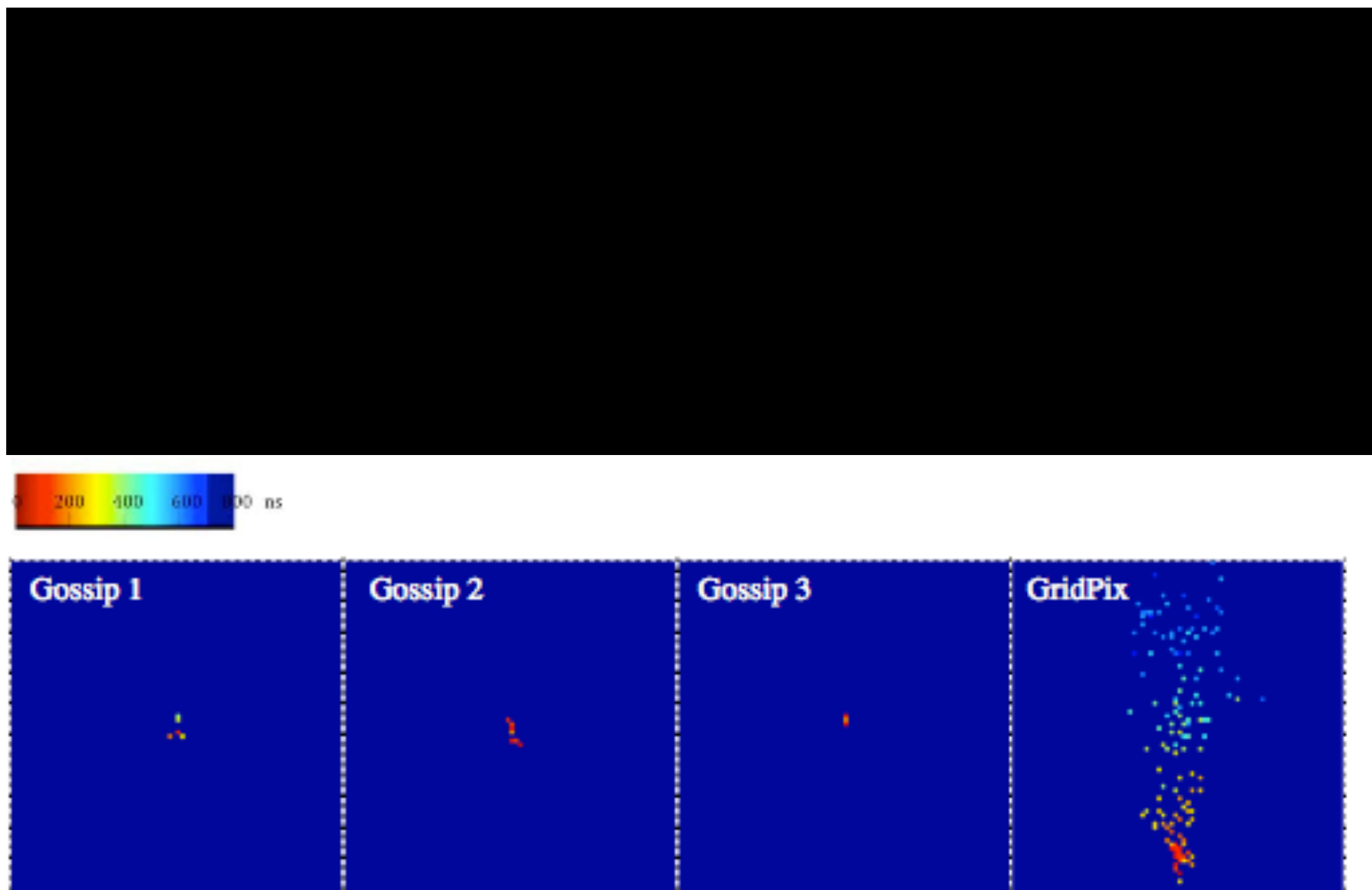


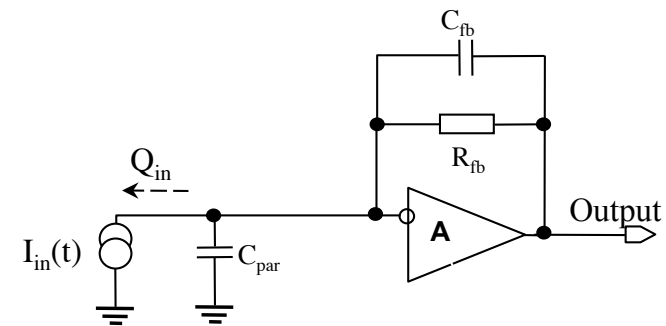
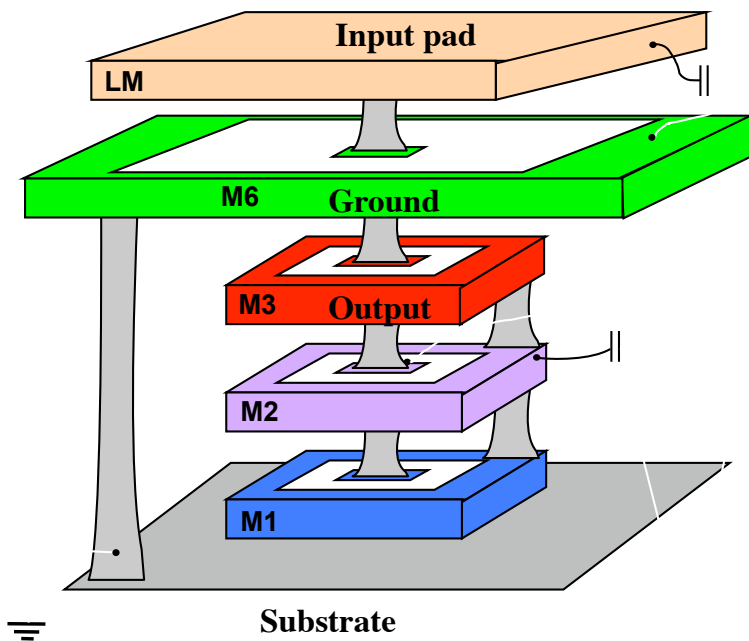
Fig. 10. Drift time plots of a typical event from a 15 GeV  $\pi^-$  traversing three Gossip prototypes and a GridPix detector with 20 mm drift height. The drift times are indicated by colours. For better visibility only a rectangle of 80\*80 pixels is displayed of each detector.

# Electronics

GOSSIPO-1:

test of preamp-shaper-discriminator for  
GOSSIP

'MultiProjectWafer' in 0.13  $\mu\text{m}$  technology

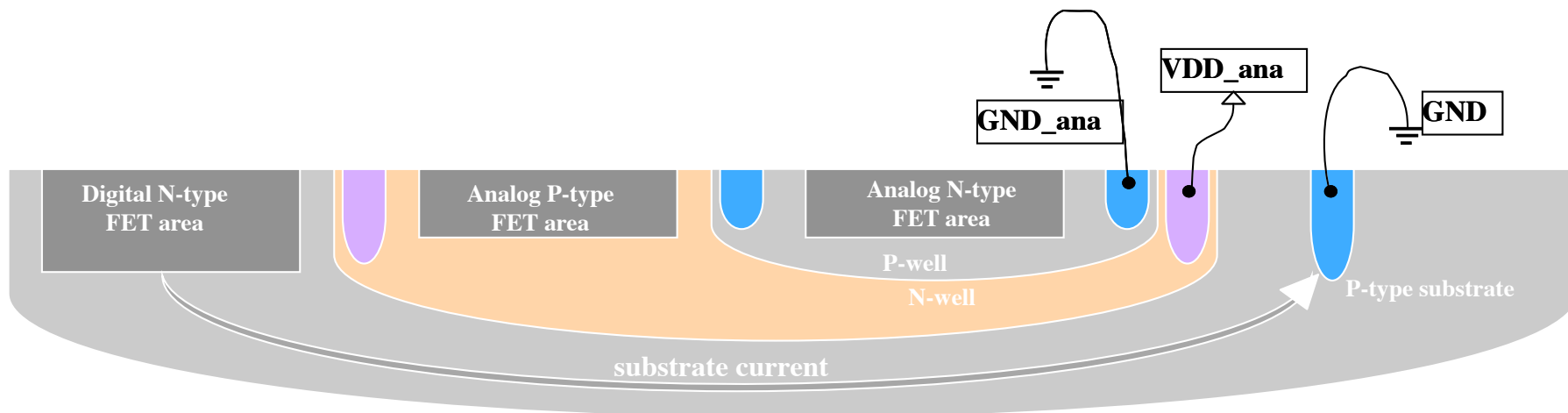


Very low (parasitic) capacitance  
at the input ( $C_{par} \rightarrow 10\text{fF}$ ).

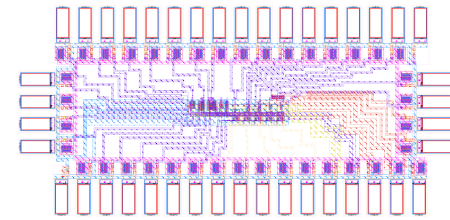
Coaxial-like layout of the input  
interconnection.

## Triple well layout in 130 nm (IBM) technology:

isolation of digital  
and  
analog sections

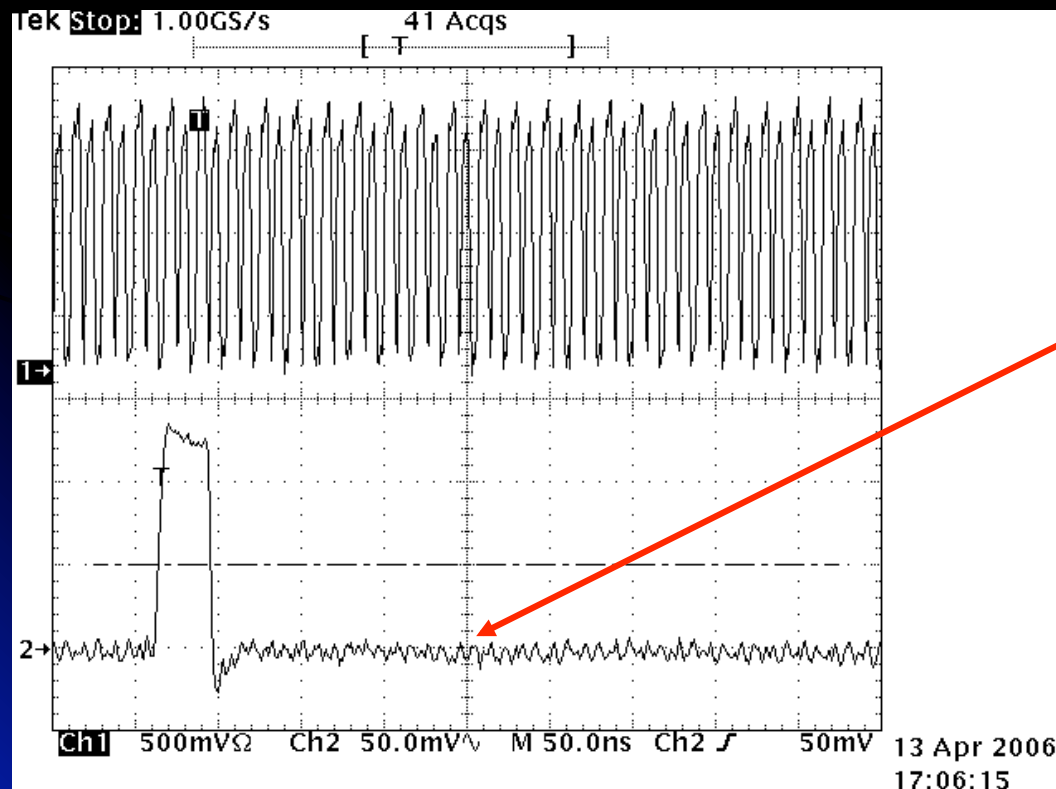


- match extreme small source capacity: 15 fF
- peaking time: 40 ns
- noise (expected: 60 e<sup>-</sup> input eq.)
- power: 2  $\mu$ W/pixel (!)



GOSSIPO chip, submitted on December 12, 2005.

GOSSIPO chip  
Submitted December 2005.



- Input noise eq. reached
- No effect of digital switching within pixel

MultiProject Wafer:

Vladimir Gromov/NIKHEF  
CERN Micro-electronics group

# GOSSIPO-2

test of preamp-shaper-discriminator

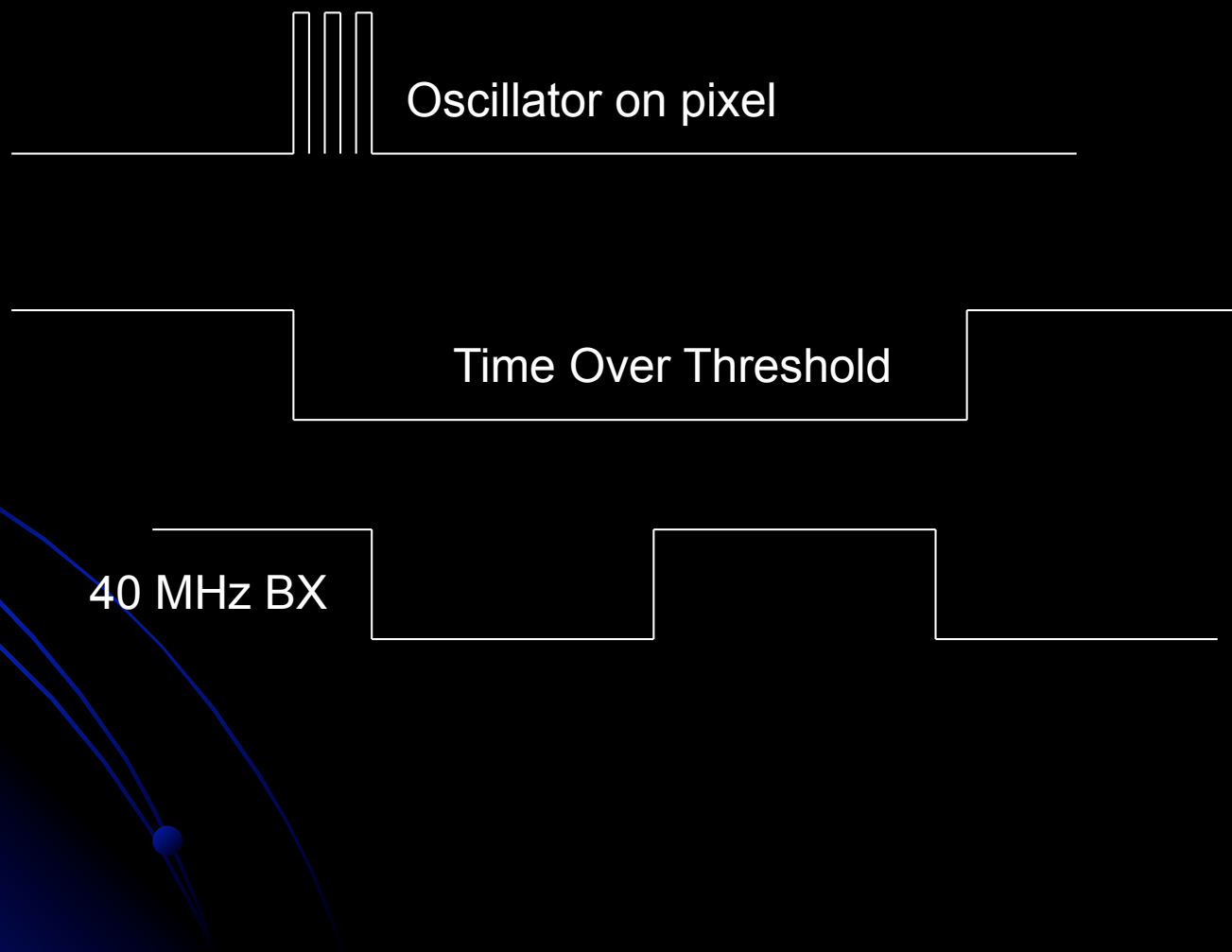
+

700 MHz TDC per pixel

- 0.13  $\mu\text{m}$  technology
- containing 16 x 16 pixels
- Submission Nov 2006
- Can be used for GOSSIP demo!

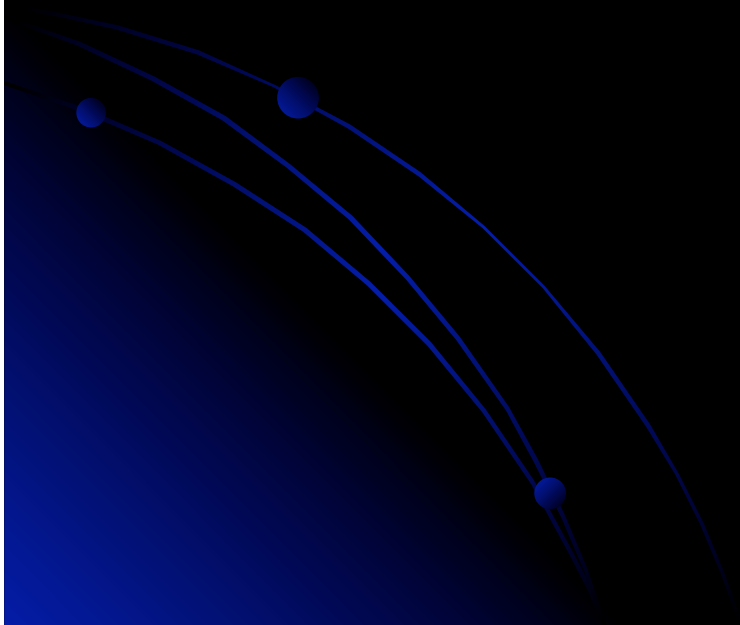


# 1 ns TDC per pixel



Gossipo-3

In collaboration with Bonn [FE-I4]  
Preparation of TimePix-2 (TPX-2)



# TimePix-2

Medipix-1

Medipix-2

250 nm technology

TimePix

Medipix-3

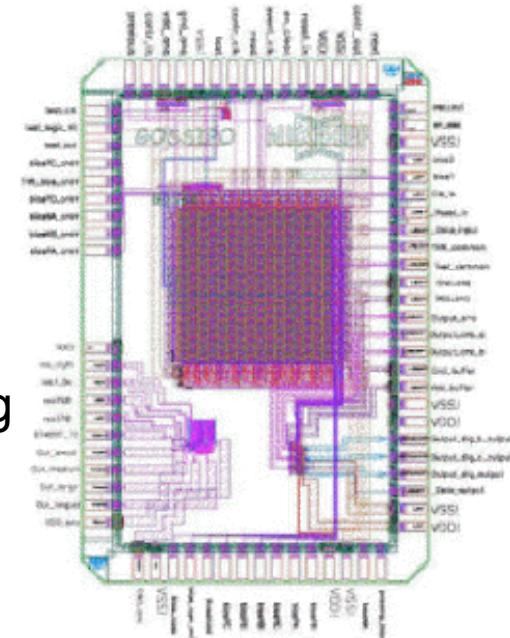
130 nm technology

TimePix-2

Gossipo-2 MPW

600 MHz osc  
in each pixel

Low-noise,  
low power analog  
input



TimePix-2:

- TDC per pixel:  $\sigma = 1$  ns
- 'ADC' per pixel: TimeOverThreshold
- noise: 80 e- eq.
- discharge protection circuit
- fast (trigger enabled) readout

**Essentially ALL info on primary electrons in gas is extracted!**

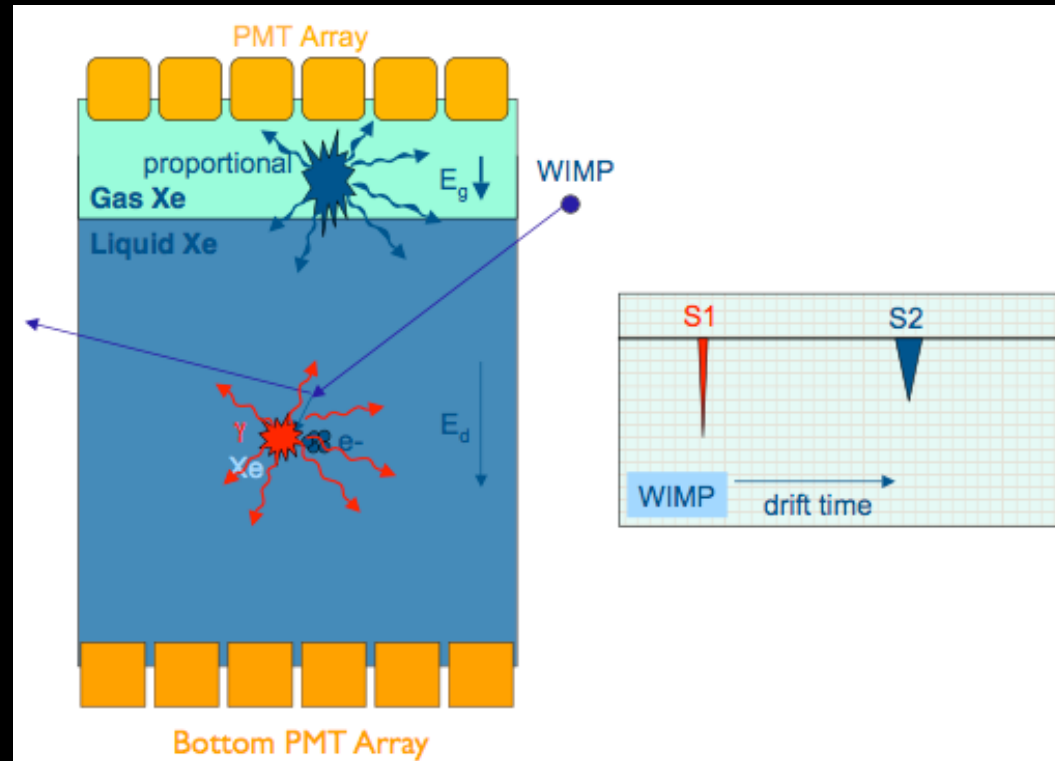
# WIMP search, bi-phase Xenon

- GridPix TPC

as

WIMP / DBD

detector

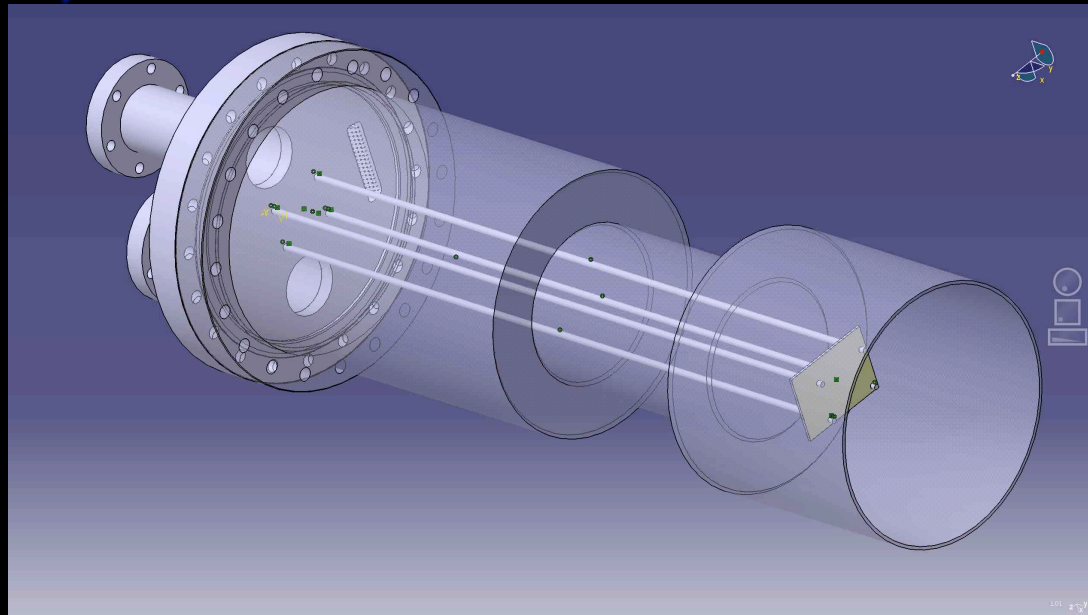


Source: Direct Searches for Dark Matter, Elena Aprile, EPS - HEP, July 21 2009, Krakow, Poland



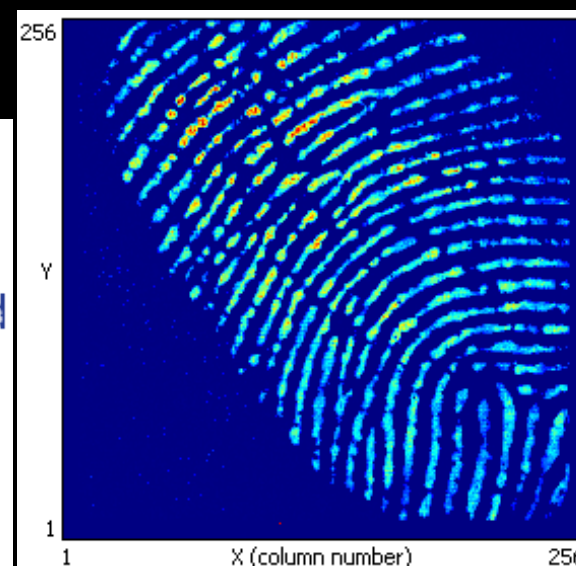
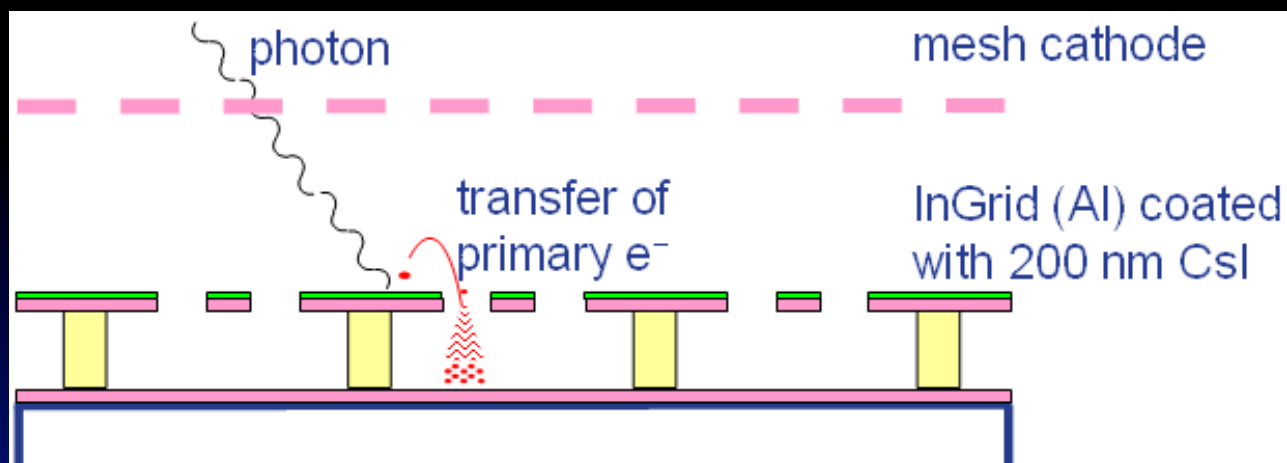
# Gridpix in Xenon: Test setup

- Collaboration DARWIN/XENON  
Columbia Univ., N.Y.



# GridPix as photon detector

- Photoelectric effect
- Future possibility:  
CsI layer on grid

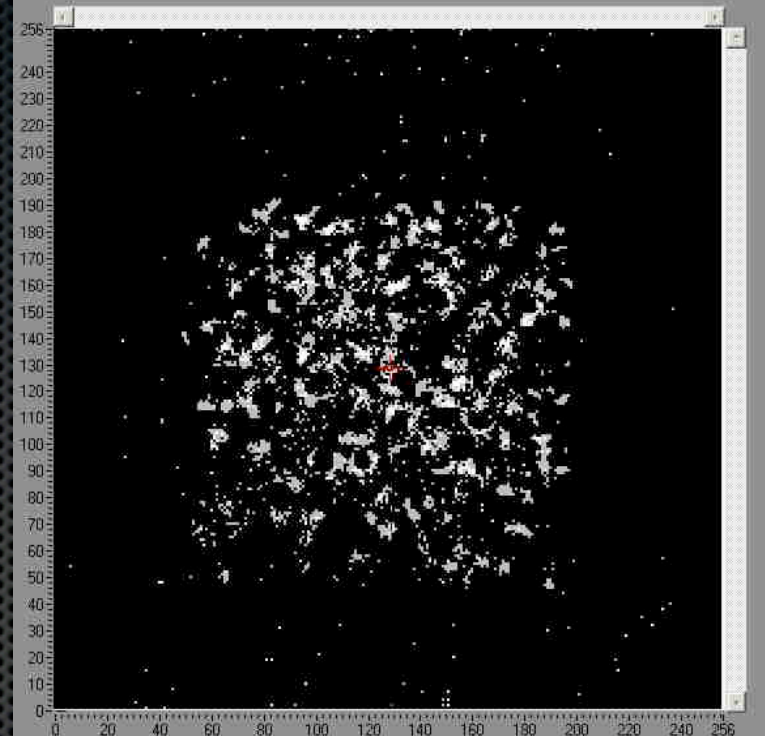




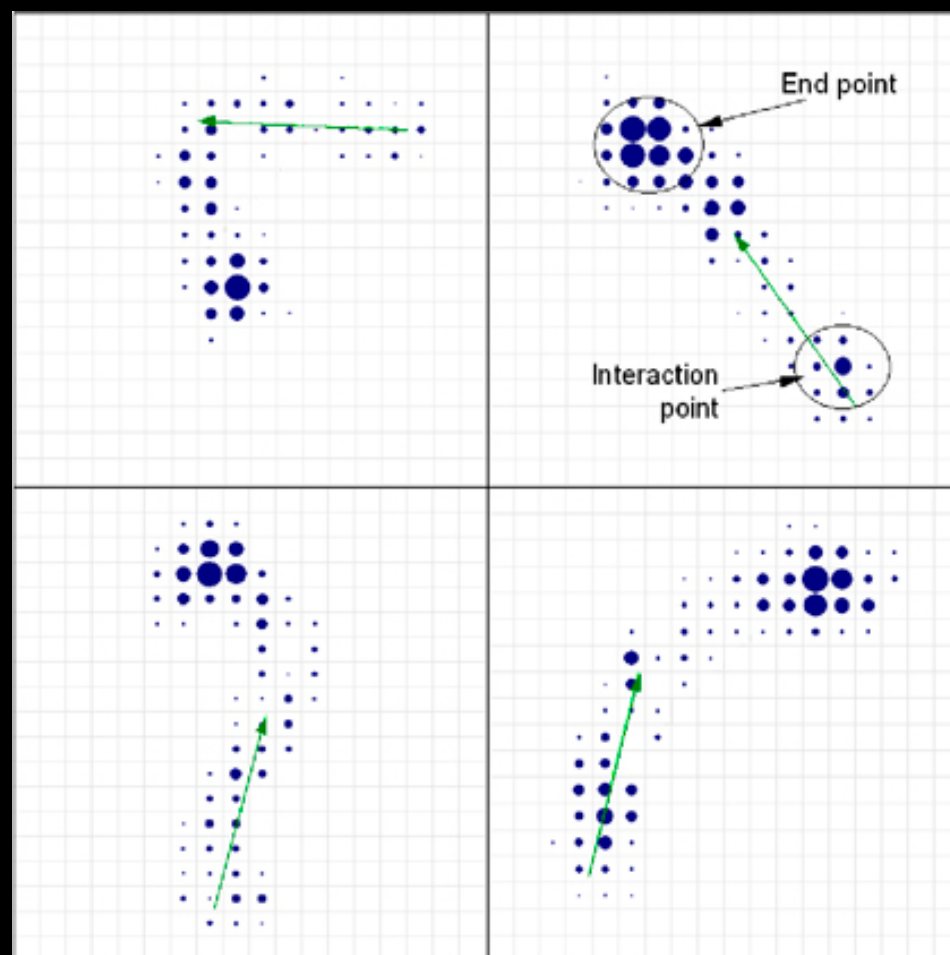
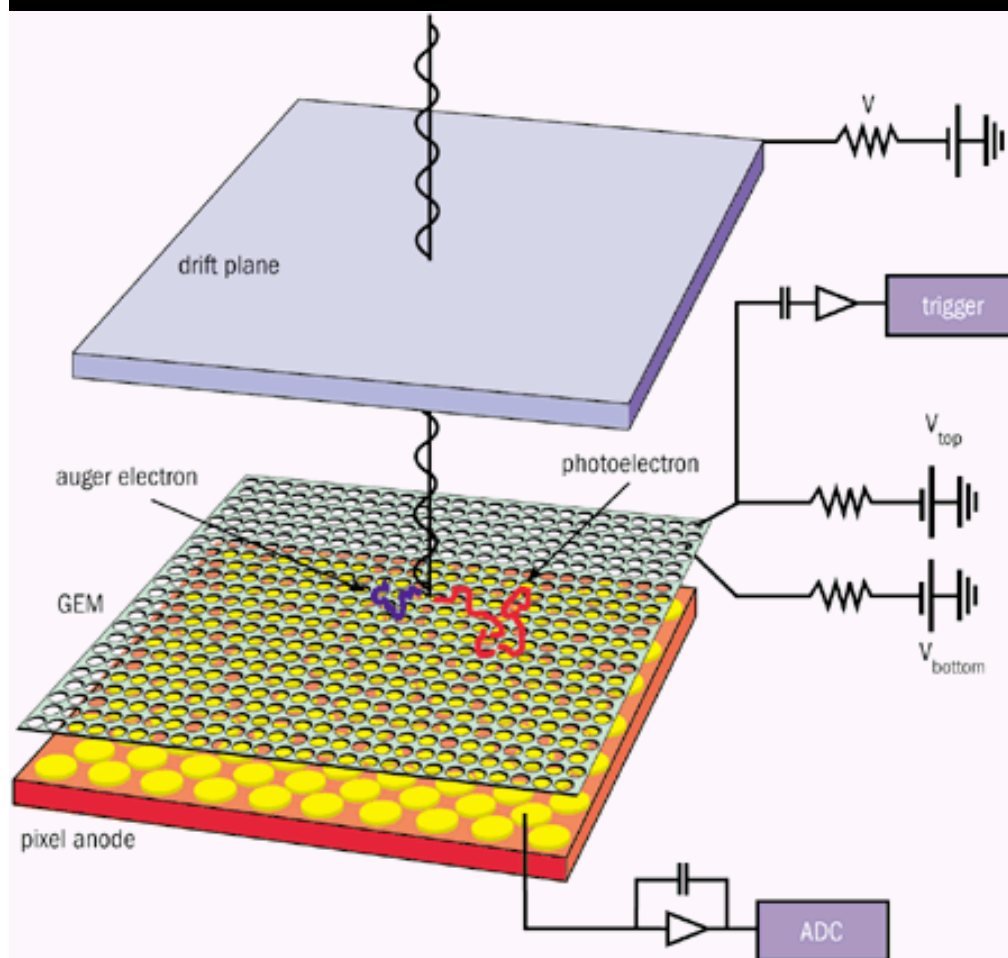
# PolaPix

Using a GridPix detector for the 3D detection of polarized X-ray photons

Sjoerd Nauta - Nikhef

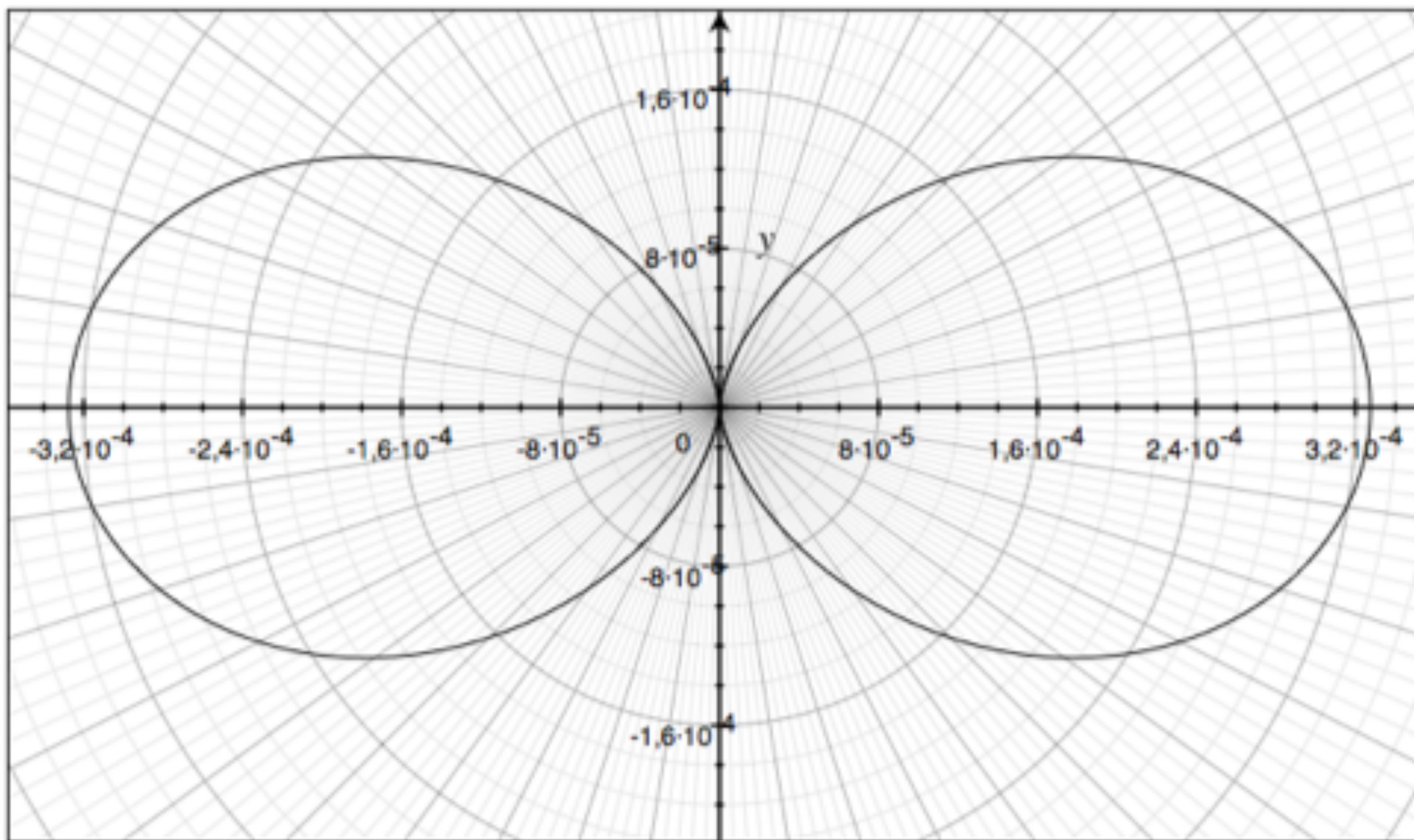






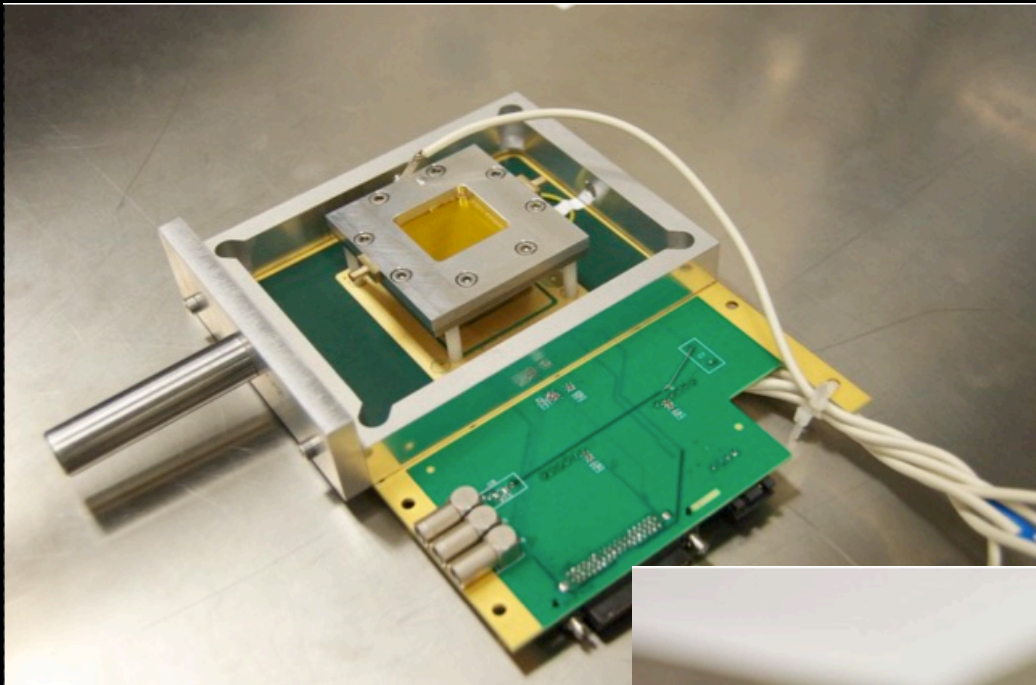
X-ray Polarimeter proposed by R. Bellazzini





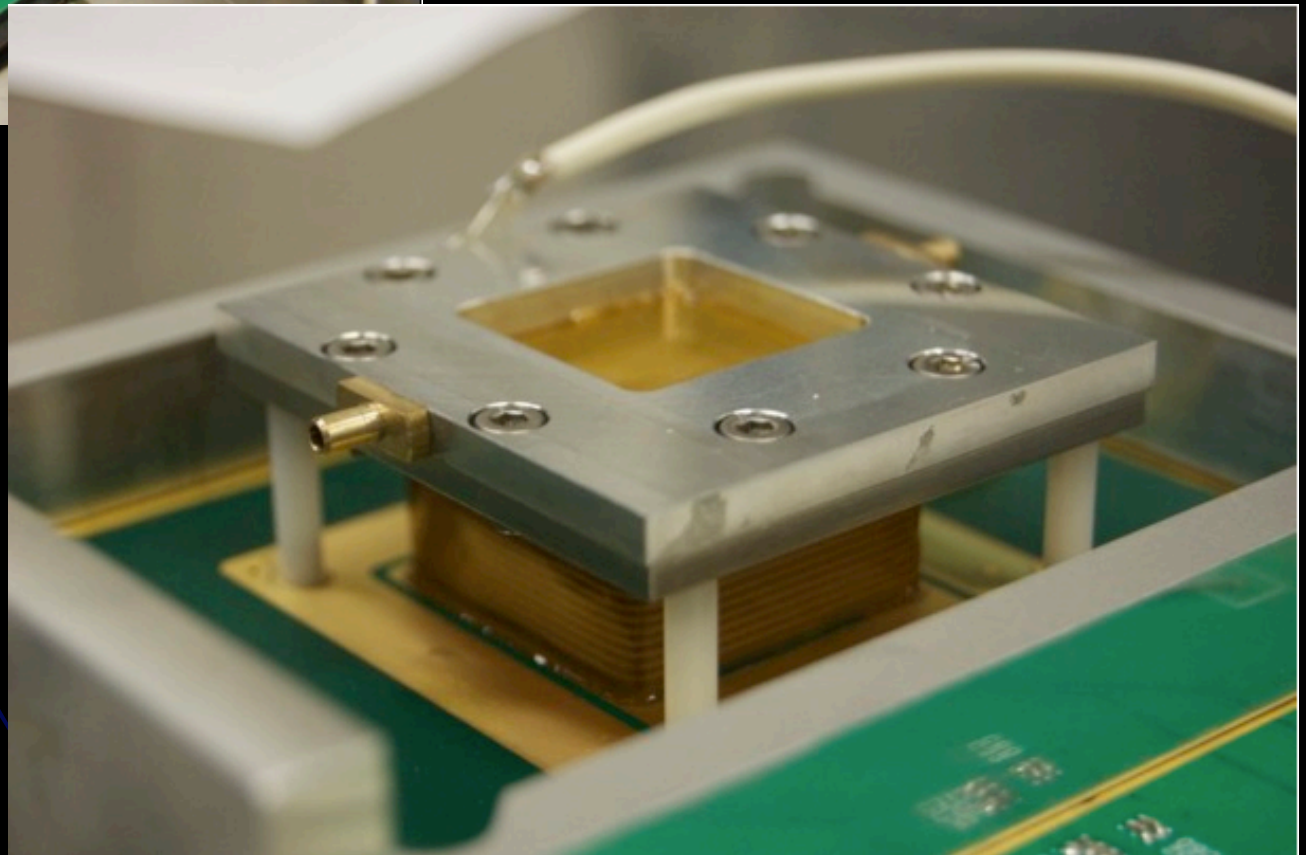
Distribution of direction of photo-electron of (fully) polarised X-rays

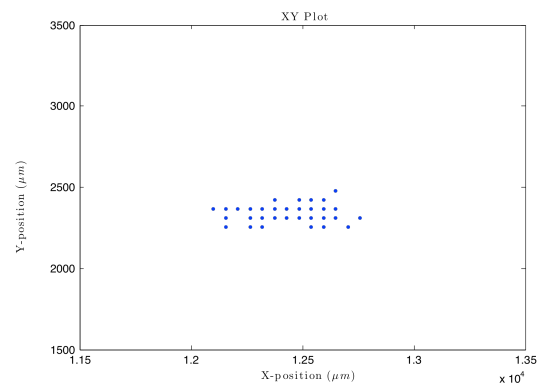
# PolaPix



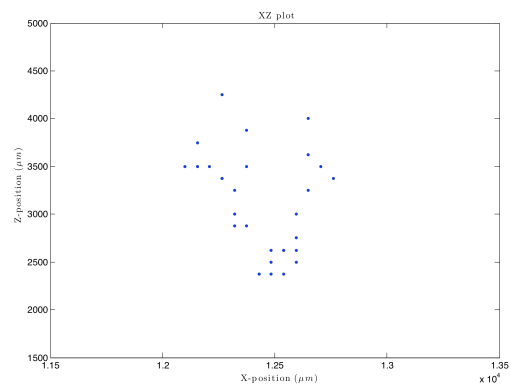
collaboration with

Erlangen Astroparticle  
Physics  
Group

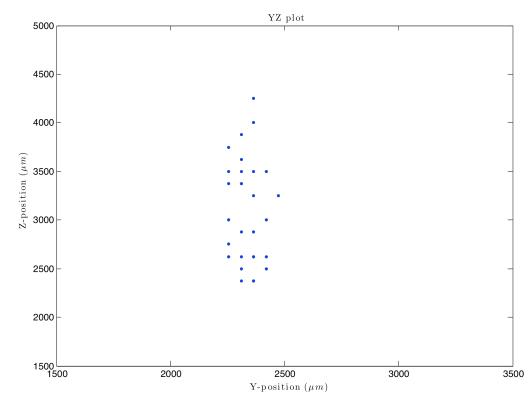




XY



XZ

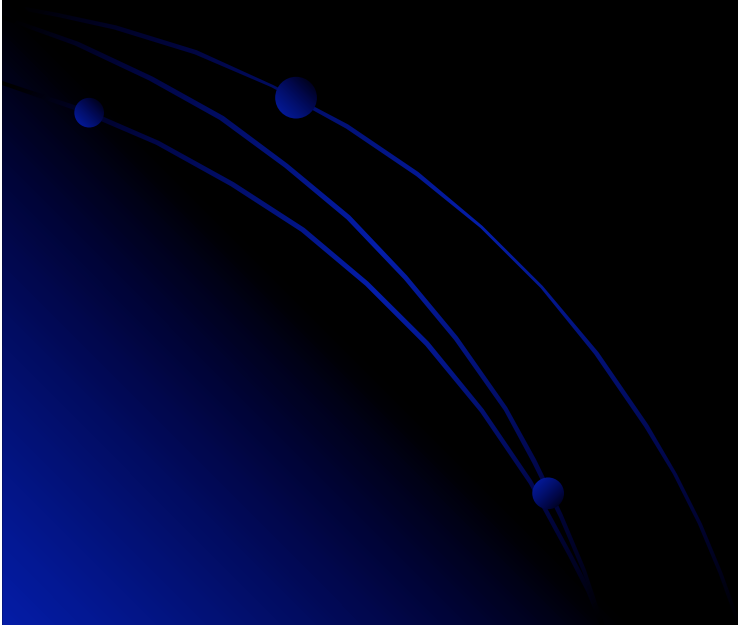


YZ

$^{55}\text{Fe}$  photoelectron in DME/CO<sub>2</sub> 50/50

## Risky project:

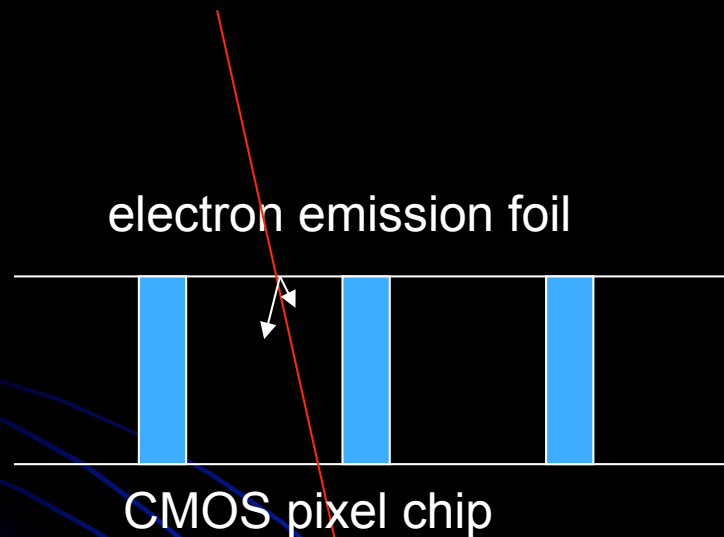
- electron emission & multiplication detectors
- eliminate gas as detection matter



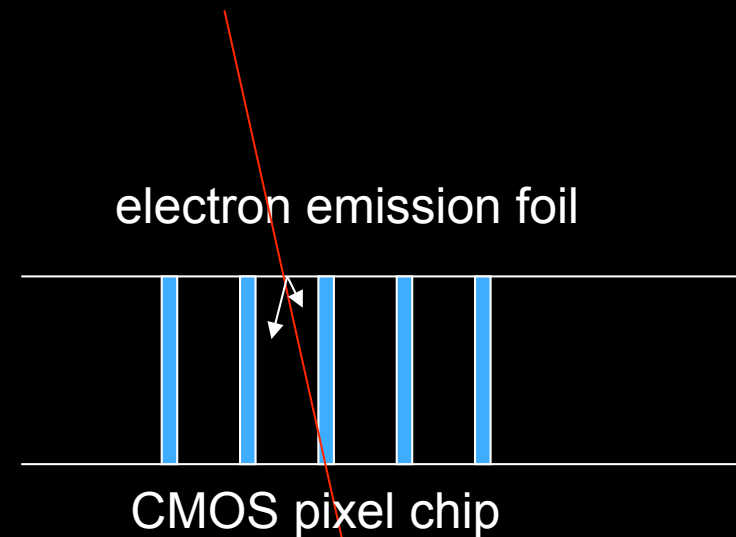
# The future:

Electron Emission Foil

MEMS made MicroChannelPlates: 200 ps time resolution: CLIC



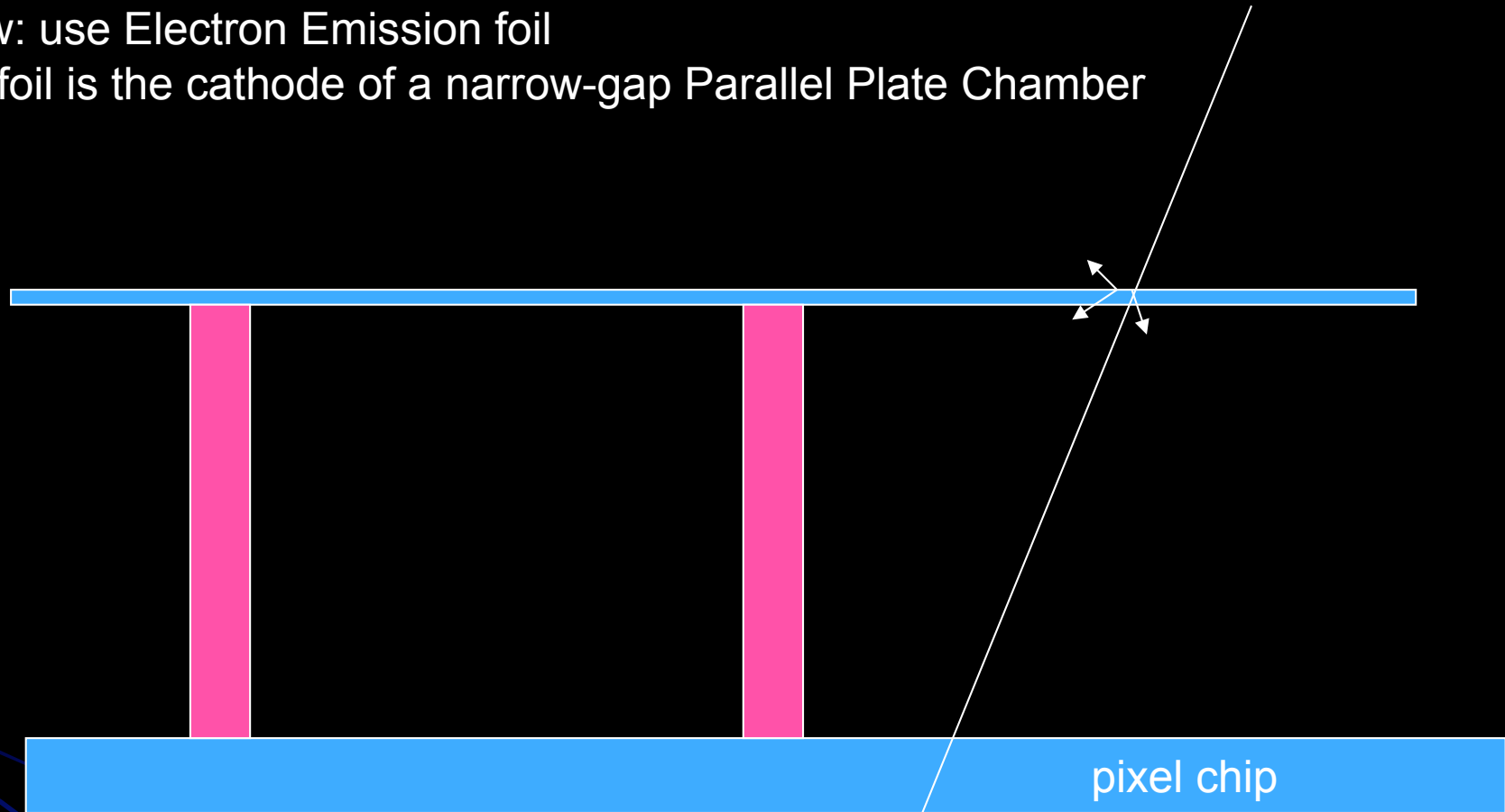
electron avalanche in gas  
EE-Foil replaces InGrid  
Parallel Plate Chamber



replace gas by vacuum  
Micro Channel Plate  
sub-ns time resolution  
Note CLIC experiments



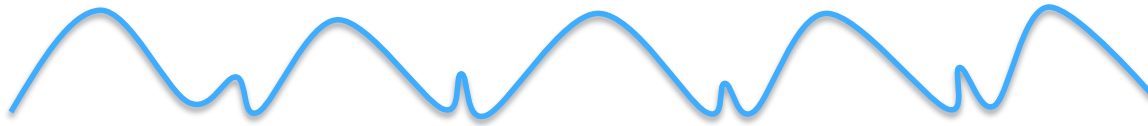
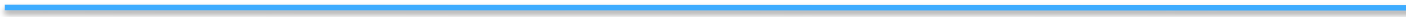
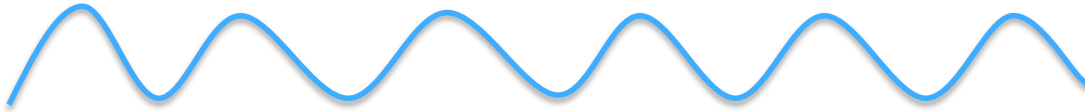
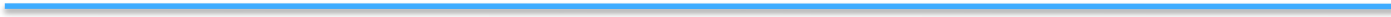
New: use Electron Emission foil  
EE foil is the cathode of a narrow-gap Parallel Plate Chamber

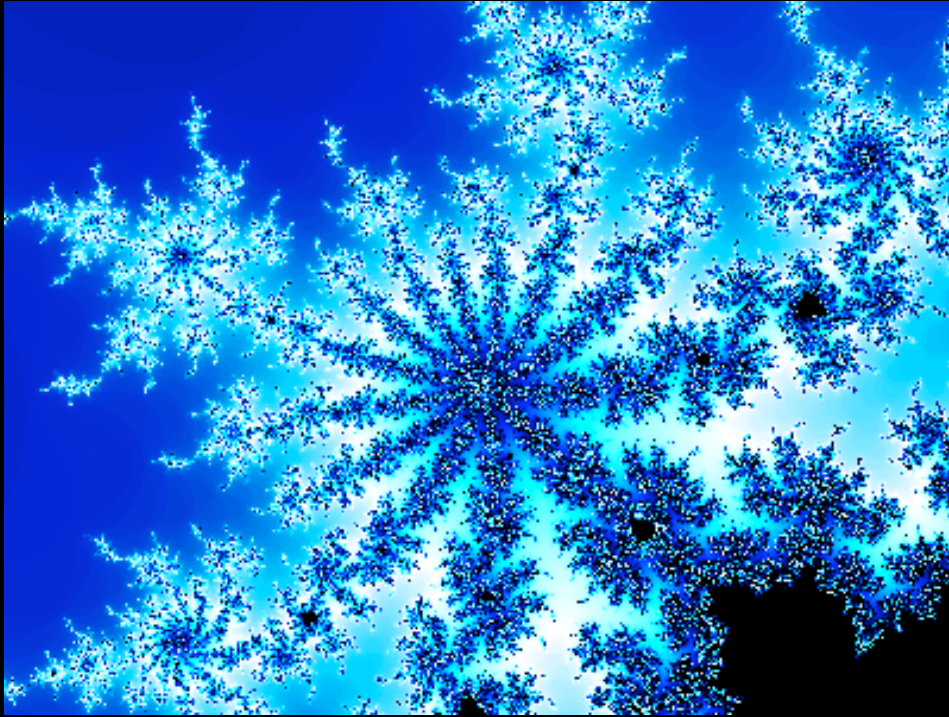


New developments in EE foil:

- low work function (CsI, bi-alkali, CVDiamond)
- surface treatment: nanotubes, CVDiamond
- Extracting electric field

MIP





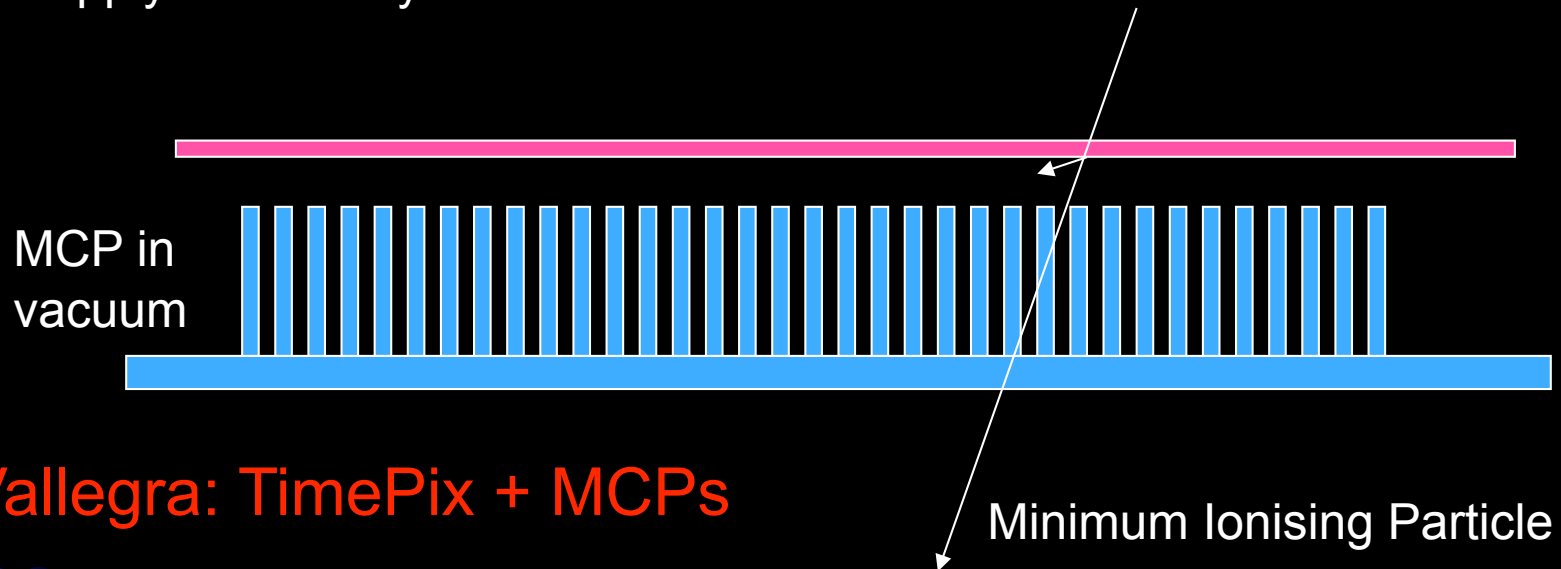
# Fractals!

- Eff Alu, Cu:  $\sim 4\%$
- Eff ceramics (Diamond, Csl,  $\text{Si}_3\text{N}_4$ ):  $20\%$ ?
- - Surface increase: factor 5
- essential: constant field strength at surface
- essential: impedance matching of material-vacuum boundary

Now wires are eliminated from gaseous detectors ('wire chambers')

Replace InGrid by Micro Channel Plate (wafer post processing tech.)

Apply 'secondary electron emission' foil



**Vallegra: TimePix + MCPs**

Minimum Ionising Particle

Time resolution  $< 200$  ps

CLIC: BXs separated by 0.5 ns!

**Gasless track detector**

# The future:

electron emission & avalanche detectors

Electron Emission Foil

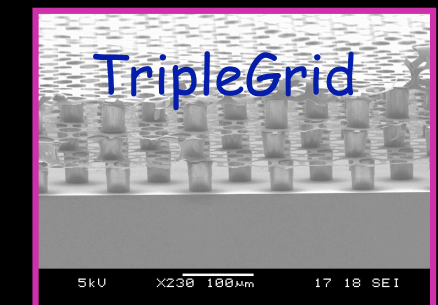
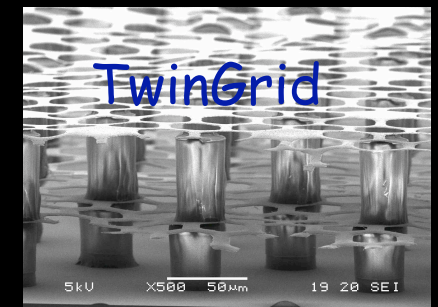
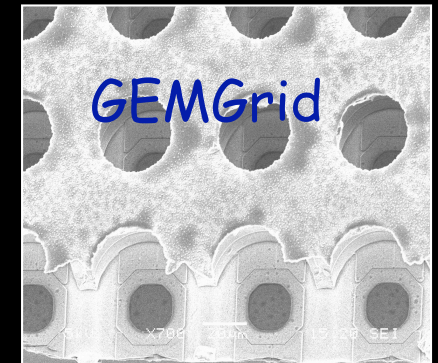
MEMS made MicroChannelPlates: 200 ps time resolution: CLIC



electron emission foil

CMOS pixel chip

replace gas by vacuum  
Micro Channel Plate (MCP)  
ElectronMultiplyingGrid (EmGrid)  
sub-ns time resolution  
Note CLIC experiments, FP420  
Works in magnetic field!





The ultimate electron multiplier: **ultra thin (100 nm) dynode layers**

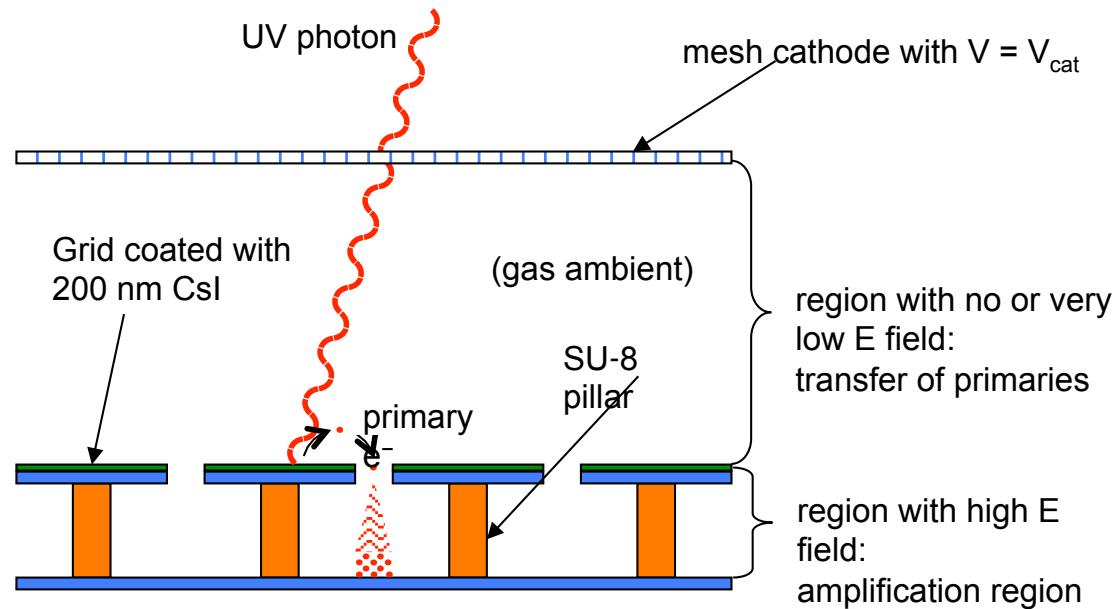
diamond

- ultra fast detector (0.1 ns)
- radiation hard
- low mass
- works in B-field!



In vacuum: no gaseous detector.....

Now operational:



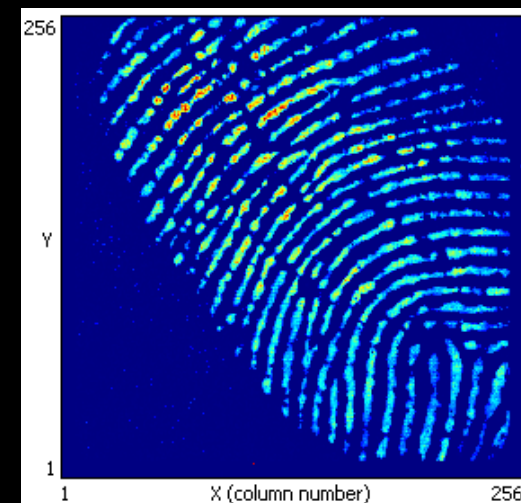
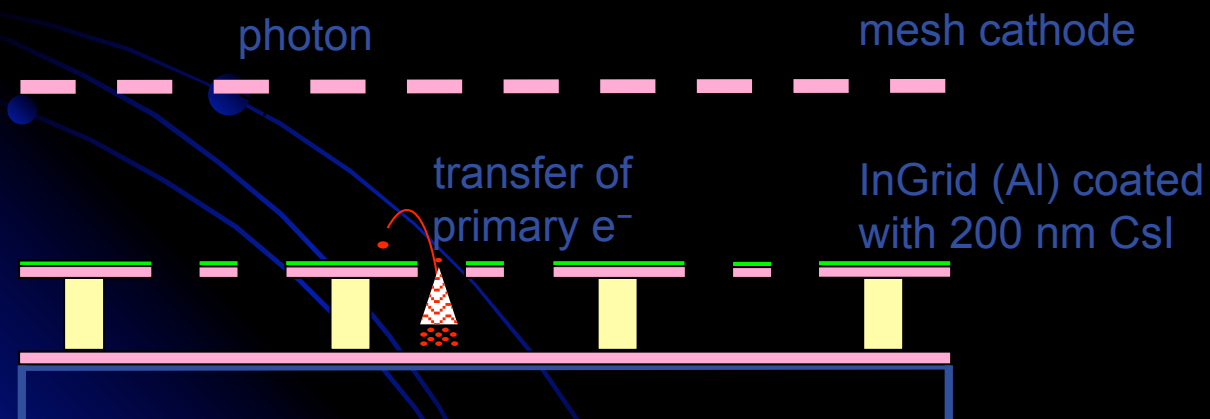
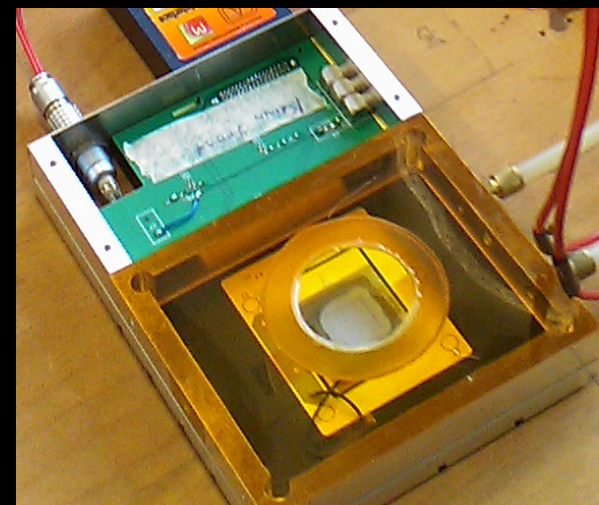
Joost Melay, Univ. Twente, MESA+  
Jurriaan Schmitz' STW project 'There is plenty of room at the top'

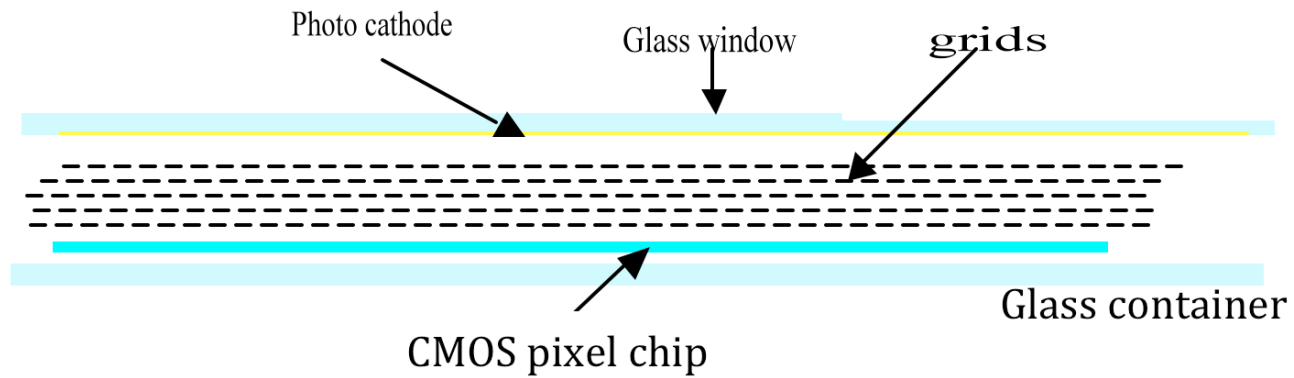
With Amos Breskin, Weizmann Institute of Science in Rehovot, Israel ,

# Photosensitive GridPix

Univ. Twente and Weizmann institute  
InGrid with CsI on alu. anode  
Detect by means of gasgain  
Better anode readout → TimePix

UV light 200-400 nm  
First test, InGrid without CsI  
UV well absorbed by my fingerprint



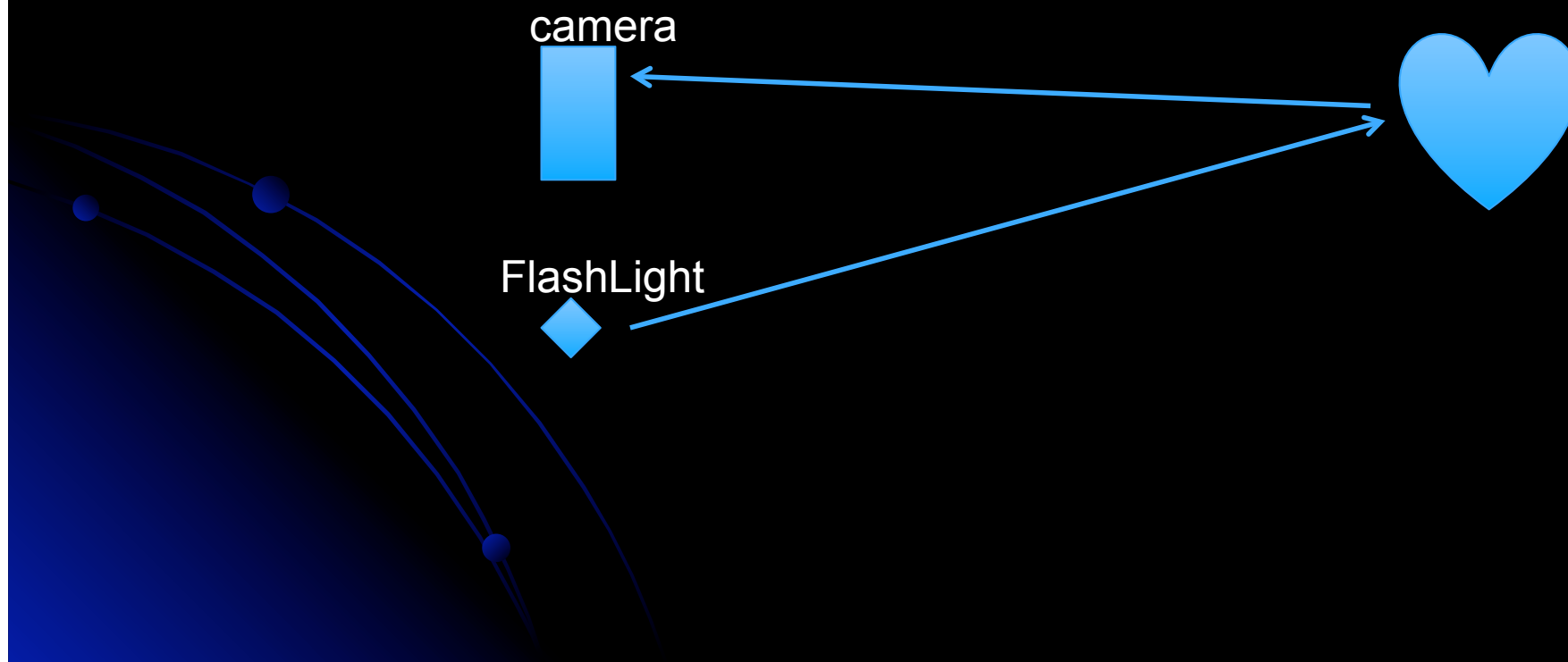


### Timed Photon Counter 'TiPC'

- spatial resolution: 30  $\mu\text{m}$
- time resolution: 10 ps
- operated in B field
- rad hard
- light

Feasible if MEMS technology enables

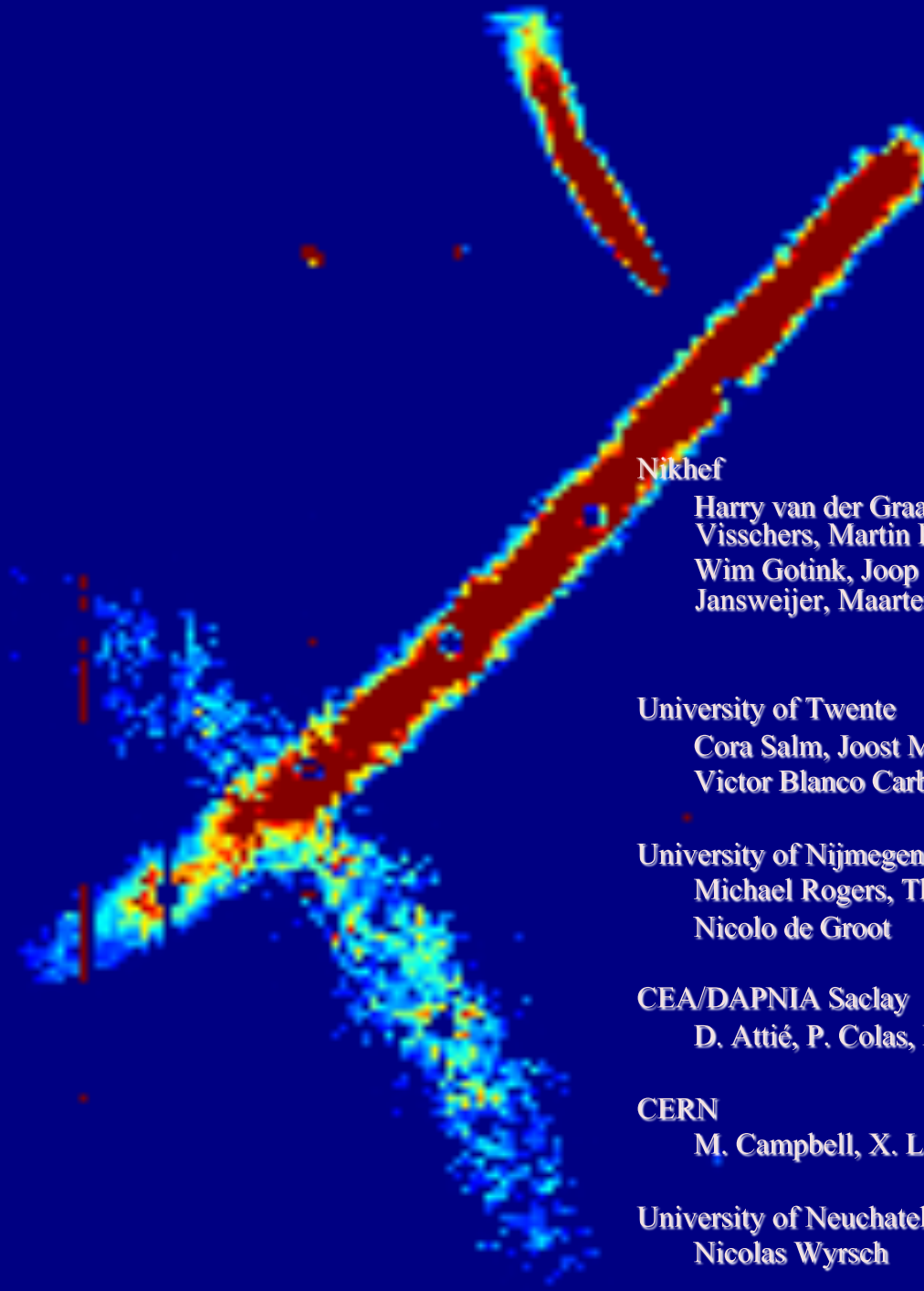
## Commercial application: 3D flash TOF camera





# Summary

- Gas-filled GridPix/Gossip detectors seem applicable as
  - tracker in HEP experiments
  - photon detectors
  - Dark Matter [DBD] experiments
  - [digital calorimeters]
- Development of Electron Emission foil
- Development of MEMS made electron multiplier
  - New PM tube: TiPC 'Topsy'



Nikhef

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Wim Gotink, Joop Rovekamp, Lucie de Nooij, Wout Kremers, Peter Jansweijer, Maarten van Dijk, Sjoerd Nauta, Jan Visser.

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Pixelman: T. Holy et al.